

Liquid-crystalline medium

The present invention relates to a liquid-crystalline medium, and to the use thereof for electro-optical purposes, and to displays containing this medium.

Liquid-crystals are used principally as dielectrics in display devices, since the optical properties of such substances can be modified by an applied voltage.

Electro-optical devices based on liquid crystals are extremely well known to the person skilled in the art and can be based on various effects. Examples of such devices are cells having dynamic scattering, DAP (deformation of aligned phases) cells, guest/host cells, TN cells having a twisted nematic structure, STN (supertwisted nematic) cells, SBE (superbirefringence effect) cells and OMI (optical mode interference) cells. The commonest display devices are based on the Schadt-Helfrich effect and have a twisted nematic structure.

The liquid-crystal materials must have good chemical and thermal stability and good stability to electric fields and electromagnetic radiation. Furthermore, the liquid-crystal materials should have low viscosity and produce short addressing times, low threshold voltages and high contrast in the cells.

They should furthermore have a suitable mesophase, for example a nematic or cholesteric mesophase for the abovementioned cells, in the usual operating temperatures, i.e. in the broadest possible range above and below room temperature. Since liquid crystals are generally used as mixtures of a plurality of components, it is important that the components are readily miscible with one another. Further properties, such as the electrical conductivity, the dielectric anisotropy and the optical anisotropy, must satisfy various requirements depending on the cell type and

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area of application. For example, materials for cells having a twisted nematic structure should have positive dielectric anisotropy and low electrical conductivity.

- 5 For example, media having large positive dielectric anisotropy, broad nematic phases, relatively low birefringence, very high specific resistance, good UV and temperature stability and low vapour pressure are desired for matrix liquid-crystal displays containing
- 10 integrated non-linear elements for switching individual pixels (MLC displays).

Matrix liquid-crystal displays of this type are known. Non-linear elements which can be used for individual

15 switching of the individual pixels are, for example, active elements (i.e. transistors). Reference is then made to an "active matrix", where a distinction can be made between two types:

- 20 1. MOS (metal oxide semiconductor) or other diodes on a silicon wafer as substrate.
2. Thin-film transistors (TFTs) on a glass plate as substrate.

25 The use of monocrystalline silicon as substrate material restricts the display size, since even modular assembly of various part-displays results in problems at the joints.

30 In the case of more-promising type 2, which is preferred, the electro-optical effect used is usually the TN effect. A distinction is made between two technologies: TFTs comprising compound semiconductors, such as, for

35 example, CdSe or TFTs based on polycrystalline or amorphous silicon. The latter technology is being worked on intensively worldwide.

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The TFT matrix is applied to the inside of one glass plate of the display, while the other glass plate carries the transparent counterelectrode on its inside. In contrast to the size of the pixel electrode, the TFT is very small and has virtually no interfering effect on the image. This technology can also be expanded to fully colour-compatible displays, in which a mosaic of red, green and blue filters is arranged in such a way that a filter element is opposite each switchable pixel.

The TFT displays usually operate as TN cells with crossed polarizers in transmission and are illuminated from the back.

The term MLC displays here covers any matrix display containing integrated non-linear elements, i.e., besides the active matrix, also displays containing passive elements, such as varistors or diodes (MIM = metal-insulator-metal).

MLC displays of this type are particularly suitable for TV applications (for example pocket TVs) or for high-information displays for computer applications (laptops) and in automobile or aircraft construction. Besides problems regarding the angle dependence of the contrast and the response times, difficulties also arise in MLC displays due to the insufficiently high specific resistance of the liquid-crystal mixtures [TOGASHI, S., SEKIGUCHI, K., TANABE, H., YAMAMOTO, E., SORIMACHI, K., TAJIMA, E., WATANABE, H., SCHIMIZU, H., Proc. Eurodisplay 84, Sept. 1984: A 210-288 Matrix LCD Controlled by Double Stage Diode Rings, p. 141 ff, Paris; STROMER, M., Proc. Eurodisplay 84, Sept. 1984: Design of Thin Film Transistors for Matrix Addressing of Television Liquid Crystal Displays, p. 145 ff, Paris]. With decreasing resistance, the contrast of a MLC display worsens, and the problem of after-image elimination can occur. Since the specific resistance of

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the liquid-crystal mixture generally drops over the life of an MLC display owing to interaction with the interior surfaces of the display, a high (initial) resistance is very important in order to obtain acceptable service lives. In particular in the case of low-volt mixtures, it was hitherto impossible to achieve very high specific resistance values. It is furthermore important that the specific resistance exhibits the smallest possible increase with increasing temperature and after heating and/or UV exposure. The low-temperature properties of the mixtures of the prior art are also particularly disadvantageous. The demands are that no crystallization and/or smectic phases occur, even at low temperatures, and the temperature dependence of the viscosity is as low as possible. The MLC displays from the prior art thus do not meet today's requirements.

Besides liquid-crystal displays which use back illumination, i.e. are operative transmissively and optionally transflectively, there is also particular interest in reflective liquid-crystal displays. These reflective liquid-crystal displays use the ambient light for information display. They thus consume significantly less energy than back-illuminated liquid-crystal displays of corresponding size and resolution. Since the TN effect is characterized by very good contrast, reflective displays of this type are readily legible even under bright ambient conditions. This is already known of simple reflective TN displays, as used, for example, in wristwatches and pocket calculators. However, the principle can also be applied to high-quality, higher-resolution active matrix-addressed displays, such as, for example, TFT displays. Here, as is already the case in the generally conventional transmissive TFT-TN displays, the use of liquid crystals of low birefringence (Δn) is necessary in order to achieve low optical retardation ($d \cdot \Delta n$). This low optical retardation results in a low viewing-angle

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dependence of the contrast, which is usually acceptable (cf. DE 30 22 818). In reflective displays, the use of liquid crystals of low birefringence is much more important than in transmissive displays, since in
5 reflective displays, the effective layer thickness, through which the light passes, is approximately twice as large as in transmissive displays of the same layer thickness.

10 Besides the lower power consumption (no back-illumination necessary), other advantages of reflective displays over transmissive displays are the space saving, which results in a very low installation depth, and the reduction in problems caused by temperature
15 gradients due to various heating by the back-illumination.

There thus continues to be a great demand for MLC displays having very high specific resistance at the
20 same time as a large working-temperature range, short response times even at low temperatures and low threshold voltage which do not have these disadvantages, or only do so to a reduced extent.

25 In TN (Schadt-Helfrich) cells, media are desired which facilitate the following advantages in the cells:

- expanded nematic phase range (in particular down to low temperatures)
- 30 - switching at extremely low temperatures (outdoor use, automobile, avionics)
- increased resistance to UV radiation (longer life)
- 35 - lower threshold (addressing) voltage
- low birefringence, especially for improved viewing-angle range.

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The media available from the prior art do not allow these advantages to be achieved while simultaneously achieving the other parameters.

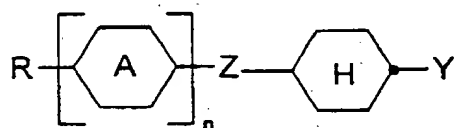
5 In the case of supertwisted (STN) cells, media are desired which enable greater multiplexability and/or lower threshold voltages and/or broader nematic phase ranges (in particular at low temperatures). To this end, a further increase in the available parameter
10 latitude (clearing point, smectic-nematic transition or melting point, viscosity, dielectric parameters, elastic parameters) is urgently desired.

15 The invention has the object of providing media for these MLC, TN or STN displays, in particular for reflective MLC displays, which do not have the abovementioned disadvantages or only do so to a reduced extent, and preferably simultaneously have very high specific resistance values and low threshold voltages
20 and low birefringence values.

It has now been found that this object can be achieved if media according to the invention are used in displays.


25 The invention thus relates to a liquid-crystalline medium based on a mixture of polar compounds of positive dielectric anisotropy, characterized in that it comprises one or more compounds of general formula I

30



in which

35 R is H, an alkyl or alkenyl radical having 1 to 15 carbon atoms which is unsubstituted,

monosubstituted by CN or CF₃ or at least monosubstituted by halogen, where one or more CH₂ groups in these radicals may also, in each case independently of one another, be replaced by -O-, -S-, , -CO-, -CO-O-, -O-CO- or -O-CO-O- in such a way that O atoms are not linked directly to one another,



is a trans-1,4-cyclohexylene ring, in which, in addition, one or two CH₂ groups may be replaced by -O- and/or -S-, or a cyclohexenylene ring,

Y is halogenated alkyl, halogenated alkenyl, halogenated alkoxy or halogenated alkenyloxy having up to 6 carbon atoms,

Z is -CH₂O-, -OCH₂-, -CH₂CH₂-, -CH=CH-, -CF₂O-, -OCF₂-, -COO-, -C₂F₄- or a single bond, and

n is 1 or 2.

The compounds of the formula I have a broad range of applications. Depending on the choice of substituents, these compounds can serve as base materials of which liquid-crystalline media are predominantly composed; however, it is also possible to add compounds of the formula I to liquid-crystalline base materials from other classes of compound in order, for example, to modify the dielectric and/or, in particular, the optical anisotropy of a dielectric of this type and/or to optimize its threshold voltage and/or its viscosity.

In the pure state, the compounds of the formula I are colourless and form liquid-crystalline mesophases in a temperature range which is favourably located for

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electro-optical use. They are stable chemically, thermally and to light.

In the media according to the invention comprising
5 compounds of the formula I, Y is preferably OCF_3 , OCHF_2 ,
 CF_3 , CHF_2 , CF_2CHF_2 , CF_2Cl , OCF_2Cl , $\text{C}_2\text{H}_4\text{CHF}_2$, CF_2CHF_2 ,
 $\text{CF}_2\text{CH}_2\text{CF}_3$, CHF_2 , OCH_2CHF_3 , OCH_2CHF_2 , OCF_2CHF_2 , $\text{O}(\text{CH}_2)_3\text{CF}_3$,
 $\text{OCH}_2\text{C}_2\text{F}_5$, $\text{OCH}_2\text{CF}_2\text{CHF}_2$, $\text{OCH}_2\text{C}_3\text{F}_7$, OCHF_2CF_3 , OC_2F_5 , OCF_2CHF_2 ,
 $\text{OCH}=\text{CF}_2$, $\text{OCF}=\text{CF}_2$, $\text{OCF}=\text{CF}_2$, $\text{OCF}=\text{CF}_2$, $\text{OCF}=\text{CF}_2$, $\text{OCF}=\text{CF}_2$, $\text{CH}=\text{CHF}$, $\text{CH}=\text{CF}_2$,
10 $\text{CF}=\text{CF}_2$, CF_2OCF_3 , in particular OCF_3 and CF_3 .

Particular preference is given to compounds of the formula I in which ring A is a trans-1,4-cyclohexane ring or a dioxane ring.

15 If R is an alkyl radical and/or an alkoxy radical, this can be straight-chain or branched. It is preferably straight-chain, has 2, 3, 4, 5, 6 or 7 carbon atoms and accordingly is preferably ethyl, propyl, butyl, pentyl,
20 hexyl, heptyl, ethoxy, propoxy, butoxy, pentoxy, hexoxy or heptoxy, furthermore methyl, octyl, nonyl, decyl, undecyl, dodecyl, tridecyl, tetradecyl, pentadecyl, methoxy, octoxy, nonoxy, decoxy, undecoxy, dodecoxy, tridecoxy or tetradecoxy.

25 Oxaalkyl is preferably straight-chain 2-oxapropyl (= methoxymethyl), 2- (= ethoxymethyl) or 3-oxabutyl (= 2-methoxyethyl), 2-, 3- or 4-oxapentyl, 2-, 3-, 4- or 5-oxahexyl, 2-, 3-, 4-, 5- or 6-oxaheptyl, 2-, 3-,
30 4-, 5-, 6- or 7-oxaoctyl, 2-, 3-, 4-, 5-, 6-, 7- or 8-oxanonyl, or 2-, 3-, 4-, 5-, 6-, 7-, 8- or 9-oxadecyl.

If R is an alkyl radical in which one CH_2 group has been
35 replaced by $-\text{CH}=\text{CH}-$, this can be straight-chain or branched. It is preferably straight-chain and has 2 to 10 carbon atoms. Accordingly, it is in particular vinyl, prop-1- or -2-enyl, but-1-, -2- or -3-enyl, pent-1-, -2-, -3- or -4-enyl, hex-1-, -2-, -3-, -4- or

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-5-enyl, hept-1-, -2-, -3-, -4-, -5- or -6-enyl, oct-1-, -2-, -3-, -4-, -5-, -6- or -7-enyl, non-1-, -2-, -3-, -4-, -5-, -6-, -7- or -8-enyl, dec-1-, -2-, -3-, -4-, -5-, -6-, -7-, -8- or -9-enyl.

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If R is an alkyl radical in which one CH₂ group has been replaced by -O- and one has been replaced by -CO-, these are preferably adjacent. These thus contain an acyloxy group -CO-O- or an oxycarbonyl group -O-CO-.

10 These are preferably straight-chain and have 2 to 6 carbon atoms.

They are accordingly in particular acetoxymethyl, propionyl-
oxy, butyryloxy, pentanoyloxy, hexanoyloxy, acetoxymethyl,
15 propionyloxymethyl, butyryloxymethyl, pentanoyloxymethyl, 2-acetoxyethyl, 2-propionyloxyethyl, 2-butyryloxyethyl, 3-acetoxypentyl, 3-propionyloxypropyl, 4-acetoxybutyl, methoxycarbonyl, ethoxycarbonyl, propoxycarbonyl, butoxycarbonyl, pentoxycarbonyl,
20 methoxycarbonylmethyl, ethoxycarbonylmethyl, propoxycarbonylmethyl, butoxycarbonylmethyl, 2-(methoxycarbonyl)ethyl, 2-(ethoxycarbonyl)ethyl, 2-(propoxycarbonyl)ethyl, 3-(methoxycarbonyl)propyl, 3-(ethoxycarbonyl)propyl or 4-(methoxycarbonyl)butyl.

25

If R is an alkyl radical in which one CH₂ group has been replaced by unsubstituted or substituted -CH=CH- and an adjacent CH₂ group has been replaced by CO or CO-O or O-CO, this can be straight-chain or branched. It is
30 preferably straight-chain and has 4 to 13 carbon atoms. Accordingly, it is in particular acryloyloxymethyl, 2-acryloyloxyethyl, 3-acryloyloxypropyl, 4-acryloyloxybutyl, 5-acryloyloxypropyl, 6-acryloyloxyhexyl, 7-acryloyloxyheptyl, 8-acryloyloxyoctyl,
35 9-acryloyloxynonyl, 10-acryloyloxydecyl, methacryloyloxymethyl, 2-methacryloyloxyethyl, 3-methacryloyloxypropyl, 4-methacryloyloxybutyl, 5-methacryloyloxypropyl, 6-methacryloyloxyhexyl 7-methacryloyloxyheptyl, 8-methacryloyloxyoctyl or 9-methacryloyloxynonyl.

If R is an alkyl or alkenyl radical which is mono-substituted by CN or CF₃, this radical is preferably straight-chain. The substitution by CN or CF₃ is in any
5 desired position.

If R is an at least mono-halogen-substituted alkyl or alkenyl radical, this radical is preferably straight-chain and halogen is preferably F or Cl. In the case of
10 multiple substitution, halogen is preferably F. The resultant radicals also include perfluorinated radicals. In the case of monosubstitution, the fluorine or chlorine substituent can be in any desired position, but is preferably in the ω-position.

15 Compounds of the formula I which contain wing groups R which are suitable for polymerization reactions are suitable for the preparation of the liquid-crystalline polymers.

20 Compounds of the formula I containing branched wing groups R may occasionally be of importance owing to better solubility in the conventional liquid-crystalline base materials, but in particular as chiral
25 dopants if they are optically active. Smectic compounds of this type are suitable as components of ferro-electric materials.

30 Compounds of the formula I having S_A phases are suitable, for example, for thermally addressed displays.

Branched groups generally contain not more than one chain branch. Preferred branched radicals R are
35 isopropyl, 2-butyl (= 1-methylpropyl), isobutyl (= 2-methylpropyl), 2-methylbutyl, isopentyl (= 3-methylbutyl), 2-methylpentyl, 3-methylpentyl, 2-ethylhexyl, 2-propylpentyl, isopropoxy, 2-methylpropoxy, 2-methylbutoxy, 3-methylbutoxy, 2-methyl-

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pentoxy, 3-methylpentoxy, 2-ethylhexoxy, 1-methylhexoxy or 1-methylheptoxy.

If R is an alkyl radical in which two or more CH₂ groups have been replaced by -O- and/or -CO-O-, this can be straight-chain or branched. It is preferably branched and has 3 to 12 carbon atoms. Accordingly, it is in particular biscarboxymethyl, 2,2-biscarboxyethyl, 3,3-biscarboxypropyl, 4,4-biscarboxybutyl, 5,5-bis-
10 carboxypentyl, 6,6-biscarboxyhexyl, 7,7-biscarboxyheptyl, 8,8-biscarboxyoctyl, 9,9-biscarboxynonyl, 10,10-biscarboxydecyl, bis(methoxycarbonyl)methyl, 2,2-bis(methoxycarbonyl)ethyl, 3,3-bis(methoxycarbonyl)propyl, 4,4-bis(methoxycarbonyl)butyl, 5,5-bis-
15 (methoxycarbonyl)pentyl, 6,6-bis(methoxycarbonyl)hexyl, 7,7-bis(methoxycarbonyl)heptyl, 8,8-bis(methoxycarbonyl)octyl, bis(ethoxycarbonyl)methyl, 2,2-bis(ethoxycarbonyl)ethyl, 3,3-bis(ethoxycarbonyl)propyl, 4,4-bis(ethoxycarbonyl)butyl or
20 5,5-bis(ethoxycarbonyl)hexyl.

Z is preferably a single bond, -COO- or a -CH₂CH₂-bridge.

25 The compounds of the formula I are prepared by methods known per se, as described in the literature (for example in the standard works, such as Houben-Weyl, Methoden der Organischen Chemie [Methods of Organic Chemistry], Georg-Thieme-Verlag, Stuttgart, to be
30 precise under reaction conditions which are known and suitable for said reactions. Use can also be made here of variants which are known per se, but are not mentioned here in greater detail. Furthermore, the compounds of the formula I can be prepared as described
35 in the patent applications DE 40 23 107 A1 and EP 0 418 362 A1.

The invention also relates to electro-optical displays (in particular STN or MLC displays having two plane-

parallel outer plates, which, together with a frame, form a cell, integrated non-linear elements for switching individual pixels on the outer plates, and a nematic liquid-crystal mixture of positive dielectric anisotropy and high specific resistance which is located in the cell) which comprise media of this type, and to the use of these media for electro-optical purposes.

The liquid-crystal mixtures according to the invention allow a significant increase in the parameter latitude which is available.

The achievable combinations of clearing point, viscosity at low temperature, thermal and UV stability, optical anisotropy and threshold voltage are far superior to the known materials from the prior art.

The requirement for a high clearing point, nematic phase at low temperature and low birefringence (Δn) and simultaneously a low threshold voltage has hitherto only been achieved inadequately. Although liquid-crystal mixtures such as, for example, MLC-6476 and MLC-6625 (Merck KGaA, Darmstadt, Germany) have comparable clearing points and low-temperature stabilities, they both have, however, much higher Δn values of about 0.075 and much higher threshold voltages of about ≥ 1.7 V or more.

While retaining the nematic phase down to -20°C , preferably down to -30°C , particularly preferably down to -40°C , and clearing points above 80°C , preferably above 90°C , particularly preferably above 100°C , the liquid-crystal mixtures according to the invention simultaneously allow birefringence values of ≤ 0.08 , preferably ≤ 0.07 , particularly preferably ≤ 0.065 , and a low threshold voltage, allowing excellent STN and MLC displays, in particular reflective MLC displays, to be achieved. In particular, the mixtures are characterized by low operating voltages. The TN thresholds are

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It goes without saying that a suitable choice of the components of the mixtures according to the invention also allows higher clearing points (for example above 110°C) to be achieved at the same time as lower dielectric anisotropy values and thus higher threshold voltages, or lower clearing points to be achieved at the same time as higher dielectric anisotropy values (for example > 12) and thus lower threshold voltages (for example < 1.5 V) while retaining the other advantageous properties. Likewise, mixtures of higher $\Delta\epsilon$ and thus lower thresholds can also be obtained at viscosities which are increased correspondingly little. The MLC displays according to the invention preferably operate at the first Gooch and Tarry transmission minimum [C.H. Gooch and H.A. Tarry, Electron. Lett. 10, 2-4, 1974; C.H. Gooch and H.A. Tarry, Appl. Phys., Vol. 8, 1575-1584, 1975], where, besides particularly favourable electro-optical properties, such as, for example, high steepness of the characteristic line and low angle dependence of the contrast (German Patent 30 22 818), a lower dielectric anisotropy is sufficient at the same threshold voltage as in an analogous display at the second minimum. Thus, significantly higher specific resistance values can be achieved using the mixtures according to the invention at the first minimum than in the case of mixtures comprising cyano compounds. Through a suitable choice of the individual components and their proportions by weight, the person skilled in the art can set the birefringence necessary for a specified layer thickness of the MLC display using simple routine methods. The requirements of reflective MLC displays are described, for example, in Digest of Technical Papers, SID Symposium 1998.

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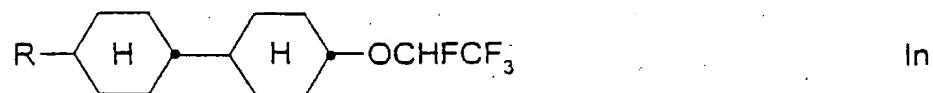
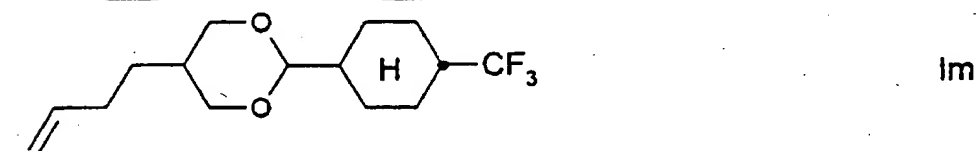
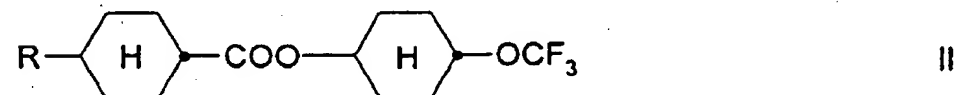
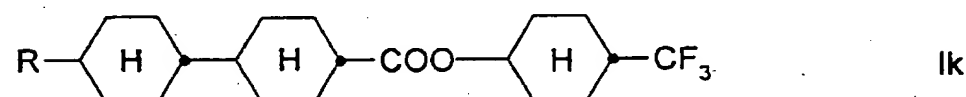
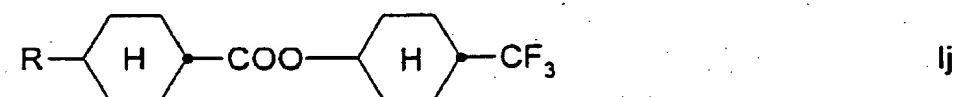
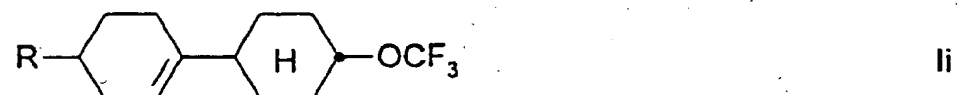
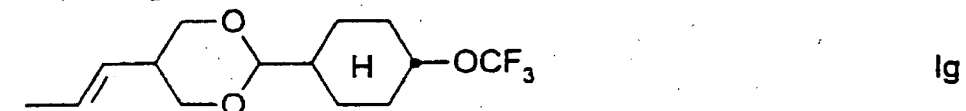
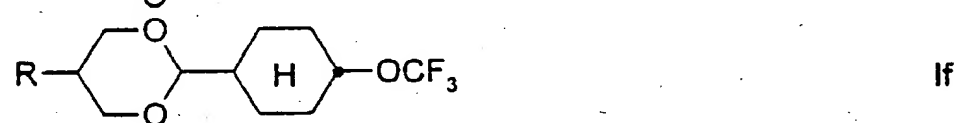
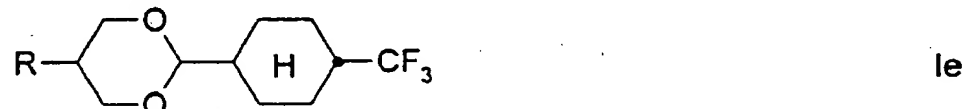
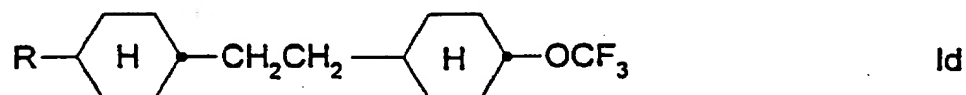
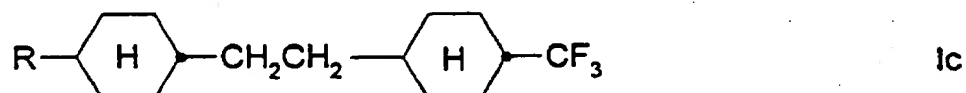
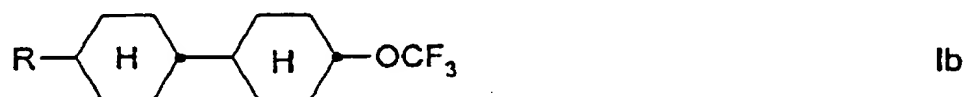
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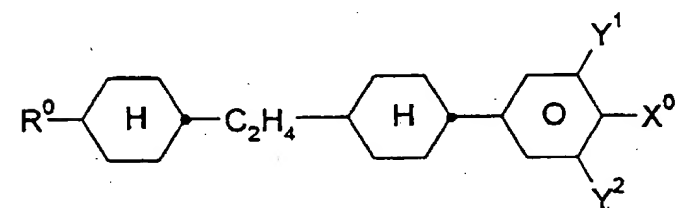
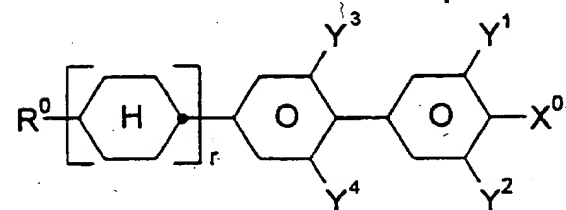
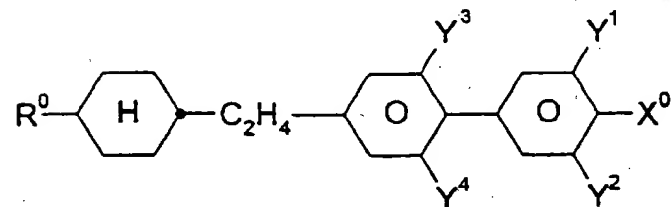
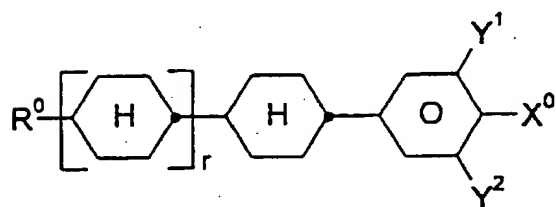
Preferred embodiments are indicated below.

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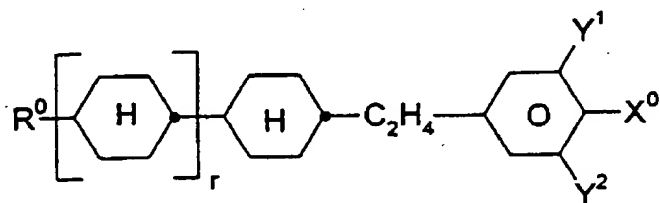


in which R is as defined in Claim 1, but is preferably a straight-chain alkyl radical;

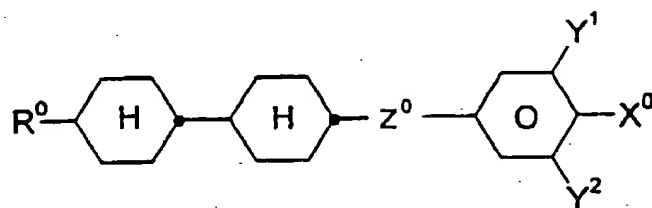
- The medium simultaneously comprises one or more compounds of the formula Ib and of the formula Ie;
- The medium simultaneously comprises one or more compounds of the formula Ij and of the formula Ik;
- The medium additionally comprises one or more compounds selected from the group consisting of the general formulae II to VIII:



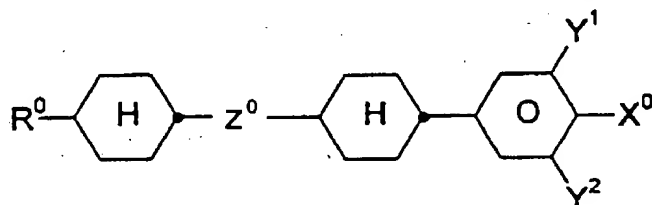
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VI



VII



VIII

in which the individual radicals have the following meanings:

R^0 : n-alkyl, oxaalkyl, fluoroalkyl or alkenyl, in each case having up to 9 carbon atoms;

X^0 : F, Cl, halogenated alkyl or alkoxy having 1 to 6 carbon atoms or halogenated alkenyl having 2 to 6 carbon atoms;

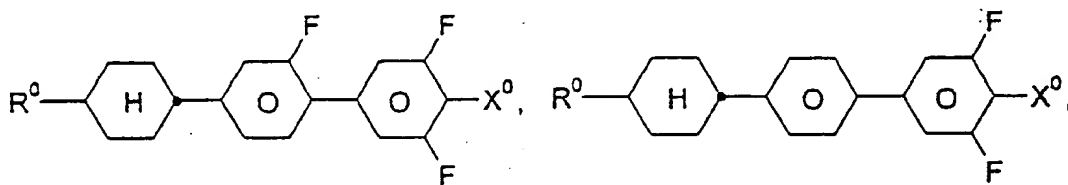
Z^0 : $-\text{C}_4\text{H}_8-$, $-\text{CF}_2\text{O}-$, $-\text{OCF}_2-$, $-\text{C}_2\text{F}_4-$, $-\text{CH}_2\text{O}-$, $-\text{OCH}_2-$ or $-\text{COO}-$;

Y^1 , Y^2 , Y^3 and Y^4 : each, independently of one another, H or F;

r : 0 or 1.

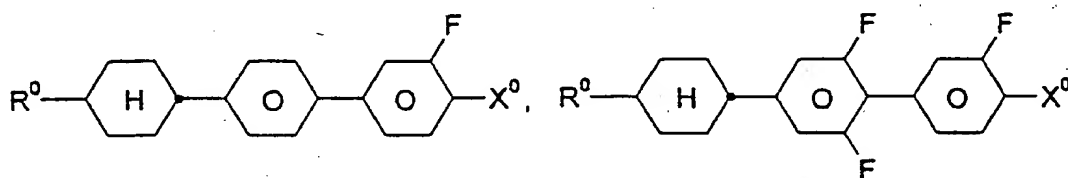
The compound of the formula IV is preferably

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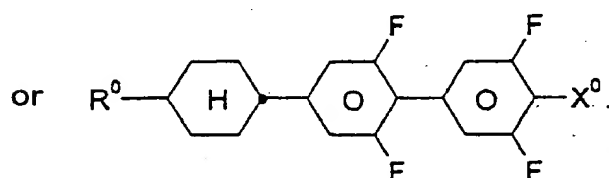
IVa

IVb



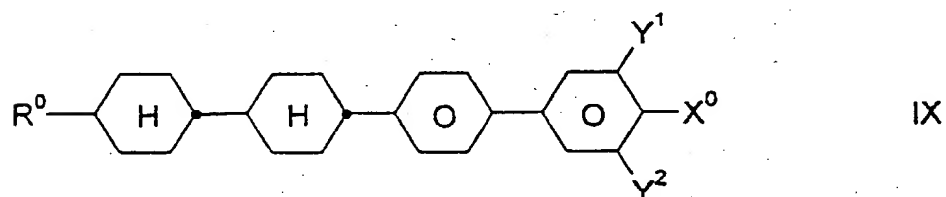
IVc

IVd

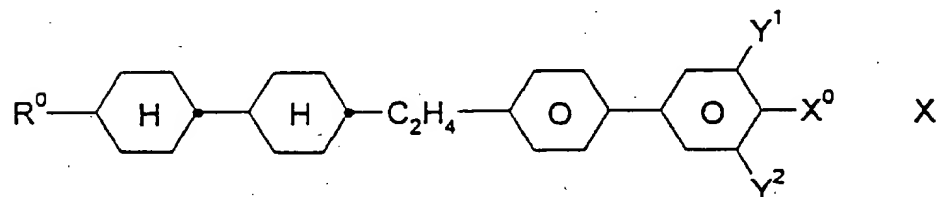


IVe

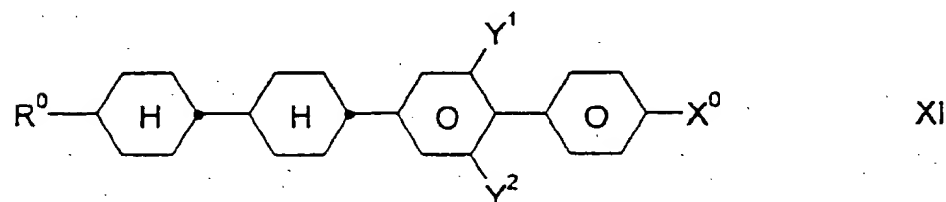
5 - The medium additionally comprises one or more compounds selected from the group consisting of the compounds of the general formulae IX to XV:



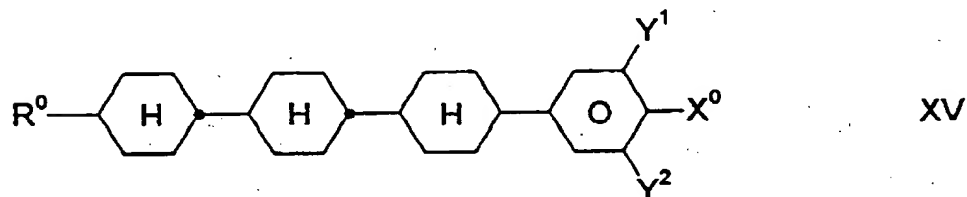
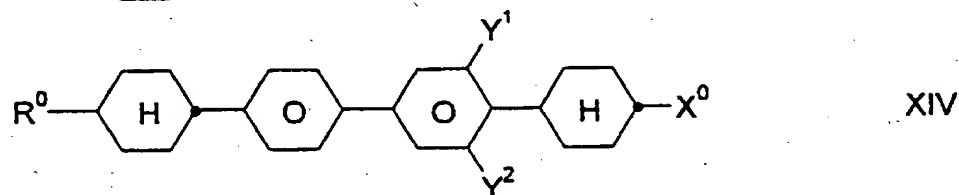
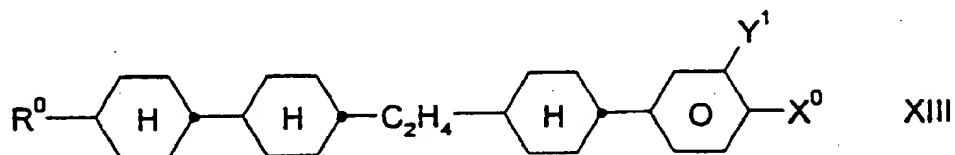
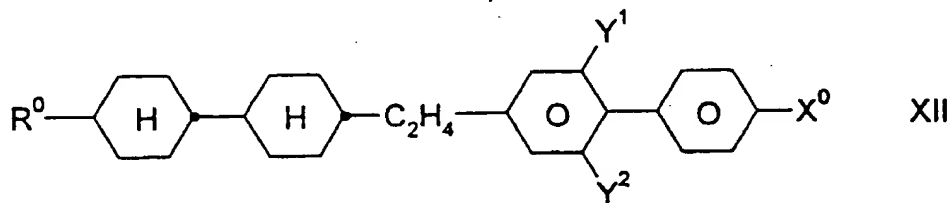
IX



X



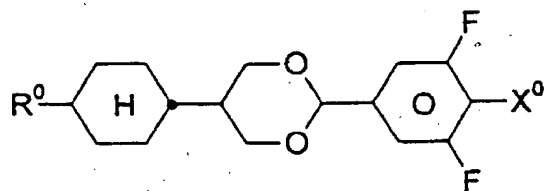
XI



5 in which R^0 , X^0 , Y^1 and Y^2 are each, independently of one another, as defined in Claim 2. X^0 is preferably F, Cl, CF_3 , OCF_3 or OCHF_2 . R^0 is preferably alkyl, oxaalkyl, fluoroalkyl or alkenyl, each having up to 6 carbon atoms.

10

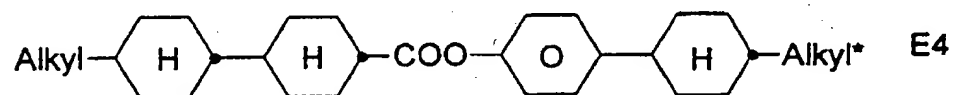
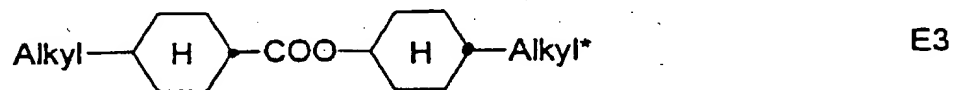
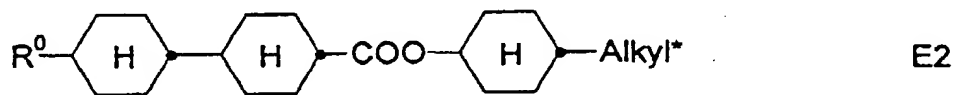
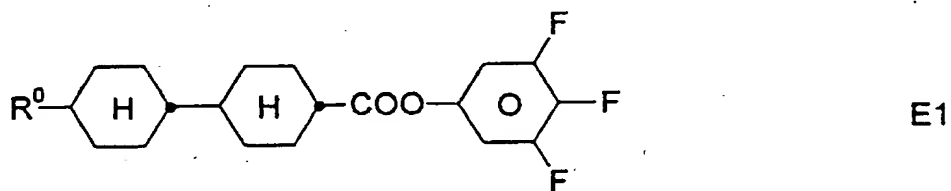
- The medium additionally comprises one or more compounds of the formula



15

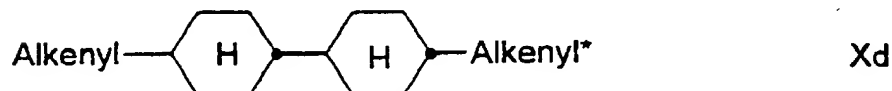
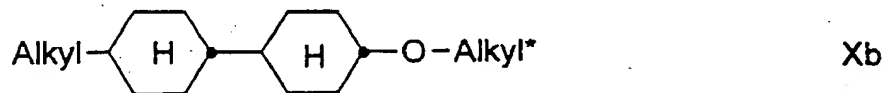
in which R^0 and X^0 are as defined above.

- The medium additionally comprises one or more ester compounds of the formulae E1 to E4:



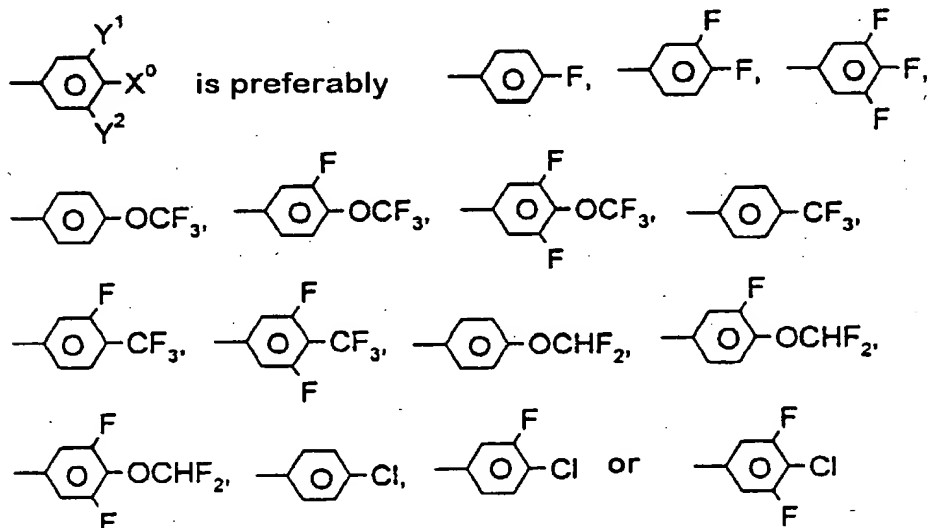
5 in which R^0 is as defined above.

- The medium additionally comprises one or more compounds of the formulae Xa to Xd:

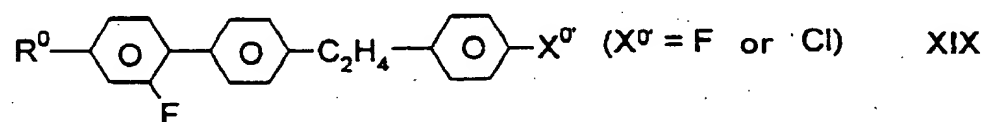
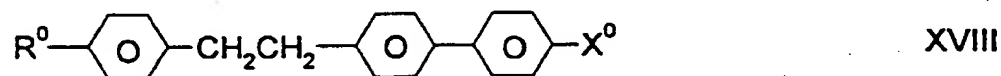
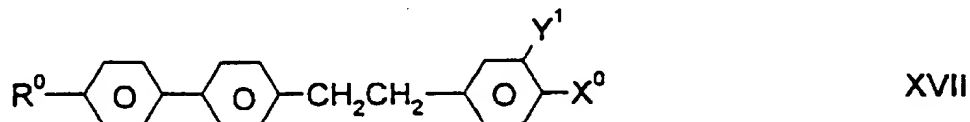
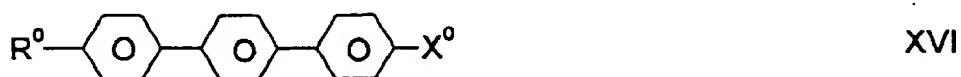


- The proportion of compounds of the formulae I to VIII in the mixture as a whole is at least 50% by weight;

- The proportion of compounds of the formula I in the mixture as a whole is from 5 to 50% by weight;
- The proportion of compounds of the formulae II to VIII in the mixture as a whole is from 20 to 80% by weight;

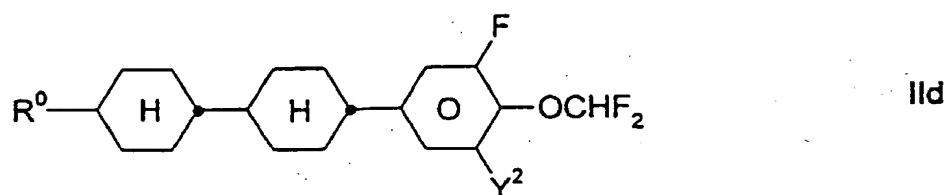
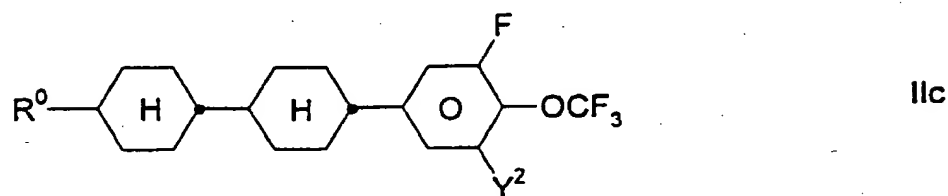
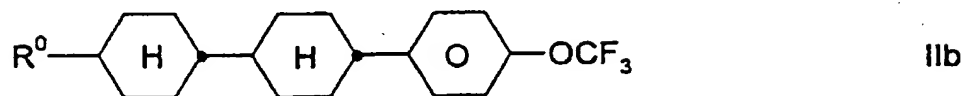
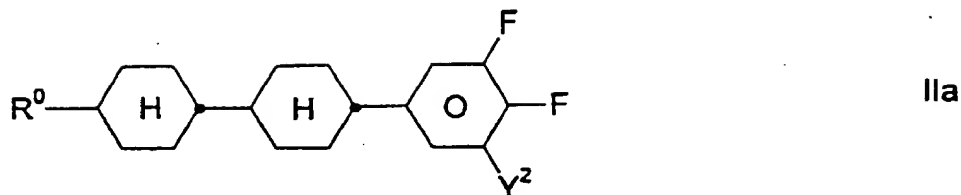


- The medium comprises compounds of the formulae II, III, IV, V, VI, VII or VIII;
- R⁰ is straight-chain alkyl or alkenyl having 2 to 7 carbon atoms;
- The medium essentially consists of compounds of the formulae I to VIII;
- The medium comprises a mixture of compounds of the formula I in which Y is CF₃ and/or OCF₃;
- The medium comprises further compounds, preferably selected from the following group consisting of the general formulae XVI to XIX;



in which R^0 and X^0 are as defined above, and the 1,4-phenylene rings may be substituted by CN, chlorine or fluorine. The 1,4-phenylene rings are preferably mono- or polysubstituted by fluorine atoms.

- The I : (II + III + IV + V + VI + VII + VIII) weight ratio is preferably 1 : 10 to 10 : 1;
- The medium essentially consists of compounds selected from the group consisting of the general formulae I to XV;
- The proportion of compounds of the formulae Xa to Xd in the mixture as a whole is 3-45% by weight, preferably 5-40% by weight, in particular 5-30% by weight;
- The proportion of compounds of the formula E1 in the mixture as a whole is 10-60% by weight, preferably 10-45% by weight, in particular 15-40% by weight;
- The compound of the formula II is preferably selected from the sub-formulae IIa to IId:



5 - The proportion of compounds of the formulae E2 and/or E3 in the mixture as a whole is 1-30% by weight, preferably 3-20% by weight, in particular 3-15% by weight;

10 - The proportion of compounds of the formula E4 in the mixture as a whole is $\leq 20\%$ by weight, in particular $\leq 10\%$ by weight.

15 It has been found that even a relatively small proportion of compounds of the formula I mixed with conventional liquid-crystal materials, but in particular with one or more compounds of the formulae II, III, IV, V, VI, VII and/or VIII results in a significant reduction in the threshold voltage and low birefringence values, where broad nematic phases with
20 low smectic-nematic transition temperatures are simultaneously observed, improving the storage stability. Particular preference is given to mixtures

which, in addition to one or more compounds of the formula I, comprise one or more compounds of the formula IV, in particular compounds of the formula IVa in which X^0 is F or OCF_3 .

5

The compounds of the formulae I to VIII are colourless, stable and readily miscible with one another and with other liquid-crystalline materials.

10 The term "alkyl" or "alkyl*" preferably covers straight-chain and branched alkyl groups having 1-7 carbon atoms, in particular the straight-chain groups methyl, ethyl, propyl, butyl, pentyl, hexyl and heptyl. Groups having 2-5 carbon atoms are generally preferred.

15

The term "alkenyl" or "alkenyl*" preferably covers straight-chain and branched alkenyl groups having 2-7 carbon atoms, in particular the straight-chain groups.

Particularly preferred alkenyl groups are

20 C_2 - C_7 -1E-alkenyl, C_4 - C_7 -3E-alkenyl, C_5 - C_7 -4-alkenyl, C_6 - C_7 -5-alkenyl and C_7 -6-alkenyl, in particular C_2 - C_7 -1E-alkenyl, C_4 - C_7 -3E-alkenyl and C_5 - C_7 -4-alkenyl.

Examples of preferred alkenyl groups are vinyl, 1E-propenyl, 1E-butenyl, 1E-pentenyl, 1E-hexenyl,

25 1E-heptenyl, 3-butenyl, 3E-pentenyl, 3E-hexenyl, 3E-heptenyl, 4-pentenyl, 4Z-hexenyl, 4E-hexenyl, 4Z-heptenyl, 5-hexenyl, 6-heptenyl and the like. Groups having up to 5 carbon atoms are generally preferred.

30 The term "fluoroalkyl" preferably covers straight-chain groups having a terminal fluorine, i.e. fluoromethyl, 2-fluoroethyl, 3-fluoropropyl, 4-fluorobutyl, 5-fluoropentyl, 6-fluorohexyl and 7-fluoroheptyl. However, other positions of the fluorine are not
35 excluded.

The term "oxaalkyl" preferably covers straight-chain radicals of the formula $C_nH_{2n+1}-O-(CH_2)_m$, in which n and m

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are each, independently of one another, from 1 to 6. n is preferably 1 and m is preferably from 1 to 6.

Through suitable choice of the meanings of R^0 and X^0 , the addressing times, the threshold voltage, the steepness of the transmission characteristic lines, etc., can be modified in the desired manner. For example, 1E-alkenyl radicals, 3E-alkenyl radicals, 2E-alkenyloxy radicals and the like generally result in short addressing times, improved nematic tendencies and a higher ratio of the elastic constants k_{33} (bend) and k_{11} (splay) compared with alkyl or alkoxy radicals. 4-Alkenyl radicals, 3-alkenyl radicals and the like generally give lower threshold voltages and smaller values of k_{33}/k_{11} compared with alkyl and alkoxy radicals.

A $-\text{CH}_2\text{CH}_2-$ group generally results in higher values of k_{33}/k_{11} compared with a single covalent bond. Higher values of k_{33}/k_{11} facilitate, for example, flatter transmission characteristic lines in TN cells with a 90° twist (in order to achieve grey shades) and steeper transmission characteristic lines in STN, SBE and OMI cells (higher multiplexability), and vice versa.

The optimum mixing ratio of the compounds of the formulae I and II + III + IV + V + VI + VII + VIII depends substantially on the desired properties, on the choice of the components of the formulae I, II, III, IV, V, VI, VII and/or VIII, and on the choice of any other components which may be present. Suitable mixing ratios within the range given above can easily be determined from case to case.

The total amount of compounds of the formulae I to XV in the mixtures according to the invention is not crucial. The mixtures can therefore comprise one or more further components in order to optimize various properties. However, the observed effect on the

5 In a particularly preferred embodiment, the media according to the invention comprise compounds of the formulae II to VIII (preferably II, III and/or IV, in particular IVa) in which X^0 is F, OCF_3 , $OCHF_2$, $OCH=CF_2$, $OCF=CF_2$ or OCF_2-CF_2H . A favourable synergistic
10 effect with the compounds of the formula I results in particularly advantageous properties. In particular, mixtures comprising compounds of the formula I and the formula IVa are distinguished by their low threshold voltages.

25 A significant difference between the displays according
to the invention and the conventional displays based on
the twisted nematic cell consists, however, in the
choice of the liquid-crystal parameters of the liquid-
30 crystal layer.

The liquid-crystal mixtures which can be used in accordance with the invention are prepared in a manner conventional per se. In general, the desired amount of the components used in a lesser amount is dissolved in the components making up the principal constituent, expediently at elevated temperature. It is also possible to mix solutions of the components in an organic solvent, for example in acetone, chloroform or

methanol, and to remove the solvent again after thorough mixing, for example by distillation. It is furthermore possible to prepare the mixtures in other conventional manners, for example by using premixtures, for example homologue mixtures, or by using so-called "multi-bottle" systems.

The dielectrics may also comprise further additives known to the person skilled in the art and described in the literature. For example, 0-15%, preferably 0-10%, of pleochroic dyes and/or chiral dopants can be added. The individual compounds added are employed in concentrations of from 0.01 to 6%, preferably from 0.1 to 3%. However, the concentration data for the other constituents of the liquid-crystal mixtures, i.e. of the liquid-crystalline or mesogenic compounds, are given without taking into account the concentration of these additives.

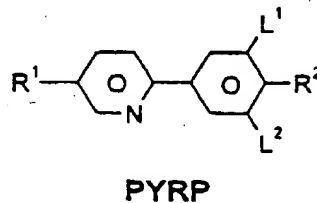
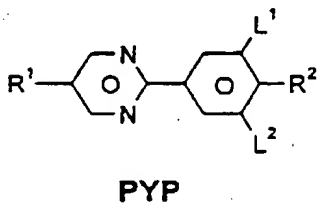
C denotes a crystalline phase, S a smectic phase, S_c a smectic C phase, N a nematic phase and I the isotropic phase.

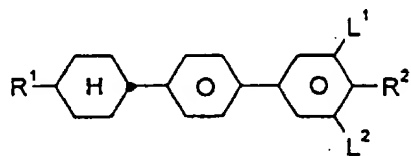
In the present application and in the examples below, the structures of the liquid-crystal compounds are indicated by means of acronyms, the transformation into chemical formulae taking place in accordance with Tables A and B below. All radicals C_nH_{2n+1} and C_mH_{2m+1} are straight-chain alkyl radicals having n and m carbon atoms respectively. n and m are in each case, independently of one another, an integer, in particular 0, 1, 2, 3, 4, 5, 6, 7, 8, 9 or 10. The coding in Table B is self-evident. In Table A, only the acronym for the parent structure is given, followed, separated from the acronym for the parent structure by a hyphen, by a code for the substituents R¹, R², L¹ and L²:

| Code for R ¹ , R ² , L ¹ , L ² | R ¹ | R ² | L ¹ | L ² |
|---|--|-------------------------------------|----------------|----------------|
| nm | C _n H _{2n+1} | C _m H _{2m+1} | H | H |
| nOm | C _n H _{2n+1} | OC _m H _{2m+1} | H | H |
| nO.m | OC _n H _{2n+1} | C _m H _{2m+1} | H | H |
| n | C _n H _{2n+1} | CN | H | H |
| nN.F | C _n H _{2n+1} | CN | H | F |
| nF | C _n H _{2n+1} | F | H | H |
| nOF | OC _n H _{2n+1} | F | H | H |
| nCl | C _n H _{2n+1} | Cl | H | H |
| nF.F | C _n H _{2n+1} | F | H | F |
| nF.F.F | C _n H _{2n+1} | F | F | F |
| nCF ₃ | C _n H _{2n+1} | CF ₃ | H | H |
| nOCF ₃ | C _n H _{2n+1} | OCF ₃ | H | H |
| nOCF ₂ | C _n H _{2n+1} | OCHF ₂ | H | H |
| nS | C _n H _{2n+1} | NCS | H | H |
| rVsN | C _r H _{2r+1} -CH=CH-C _s H _{2s} - | CN | H | H |
| V-T | CH ₂ =CH | CF ₃ | H | H |
| V2-T | CH ₂ =CH-C ₂ H ₄ | CF ₃ | H | H |
| 1V-OT | CH ₃ -CH=CH | OCF ₃ | H | H |
| rEsN | C _r H _{2r+1} -O-C _s H _{2s} - | CN | H | H |
| nAm | C _n H _{2n+1} | COOC _m H _{2m+1} | H | H |
| nOCCF ₂ .F.F | C _n H _{2n+1} | OCH ₂ CF ₂ H | F | F |

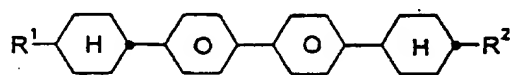
Preferred mixture components are shown in Tables A and B.

Table A:

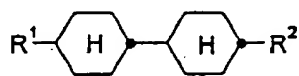




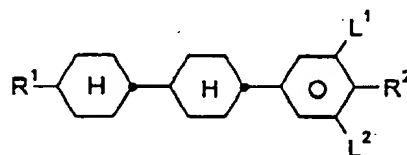
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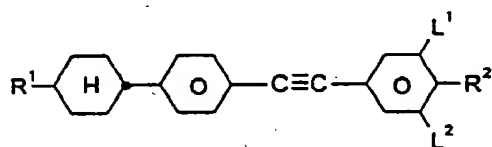
CBC



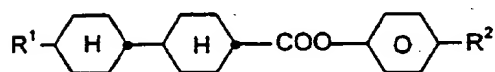
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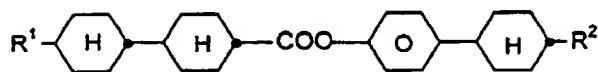
CCP



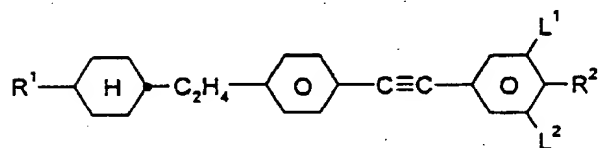
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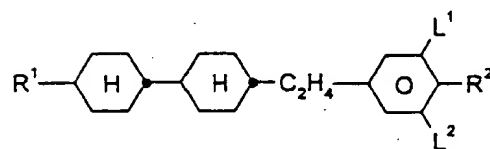
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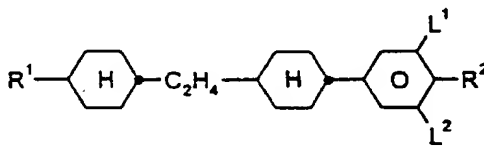
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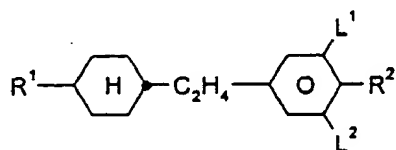
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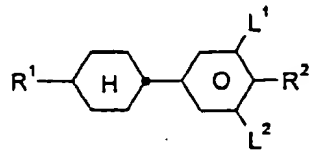
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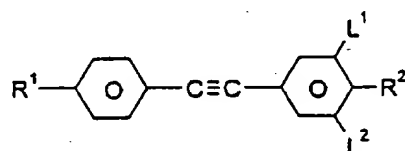
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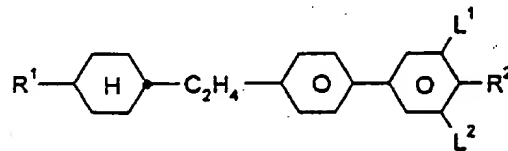
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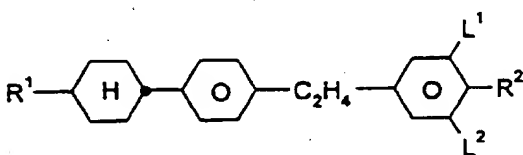
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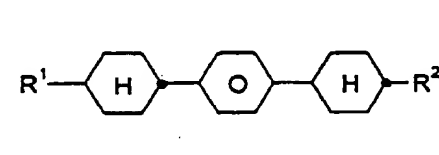
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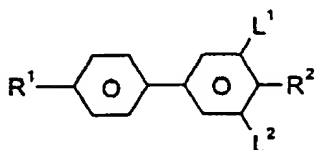
BECH



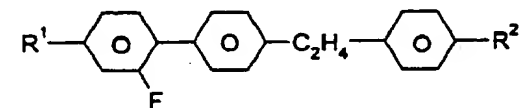
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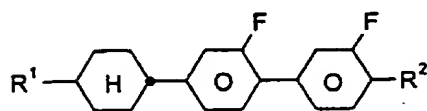
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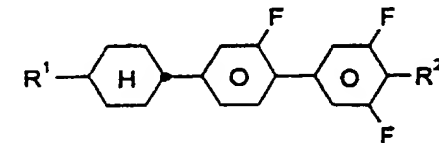
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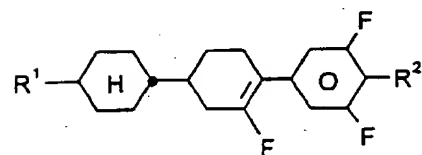
FET-nF



CGG

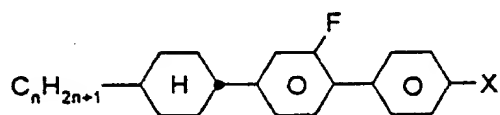


CGU

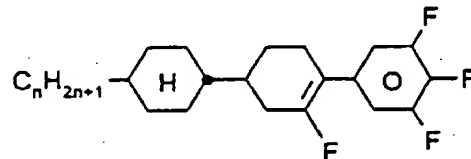


CFU

Table B:

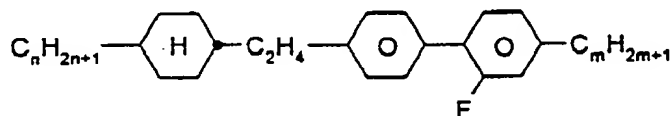
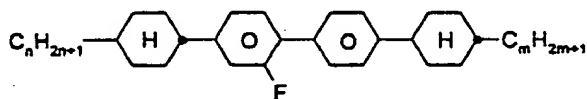


BCH-n.Fm

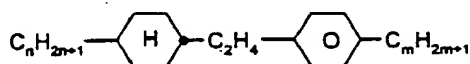


CFU-n-F

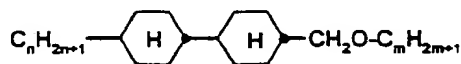
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**inm**

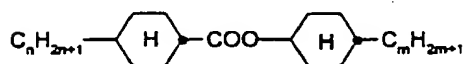
CBC-nmF



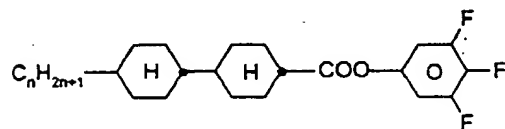
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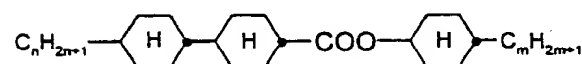
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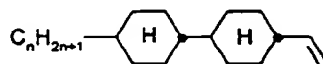
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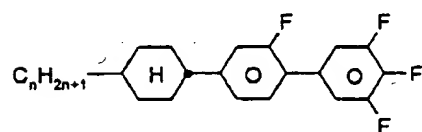
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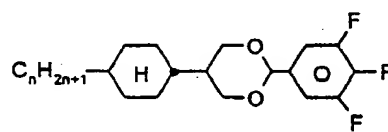
CH-nm



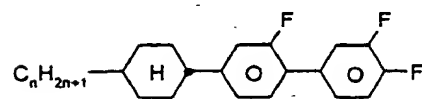
CC-5-V



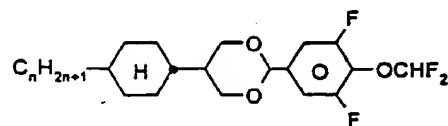
CGU-n-F



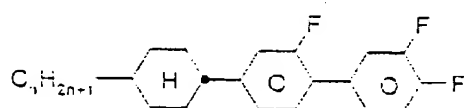
CDU-n-F



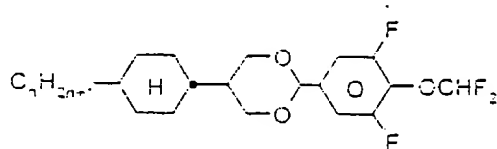
CGG-n-F



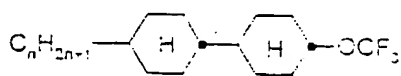
CDU-n-OD



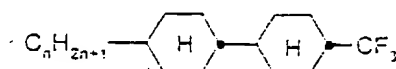
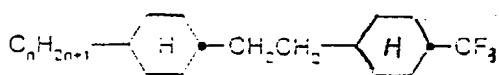
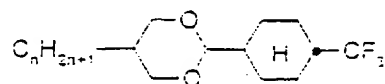
CGG-n-F



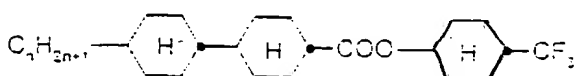
CDU-n-OD



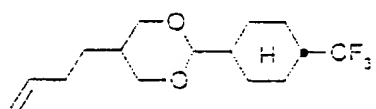
CC-n-OT


$$\text{CCH-}n\text{CF}_3$$

$$\text{ECCH-nCF}_3$$


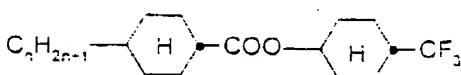
DC-n-T



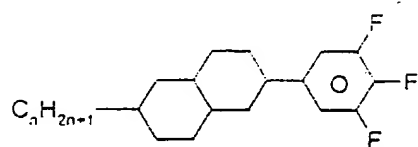
CCZC-n-T



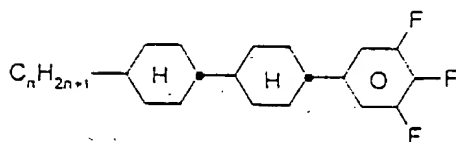
DC-V2-T



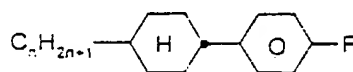
CZC-n-T



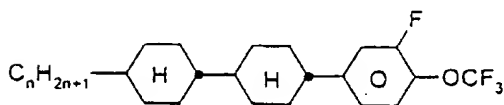
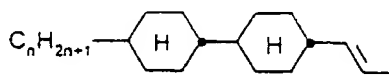
Dec-U-n-F



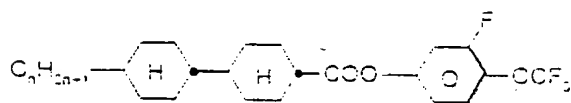
CCP-nF.F.F



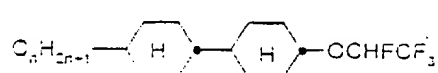
PCH-nF

CCP-nOCF₃.F

CC-n-V1

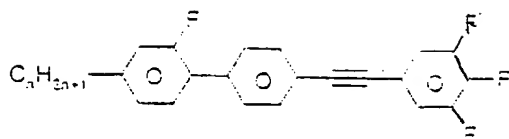


CCZG-n-OT

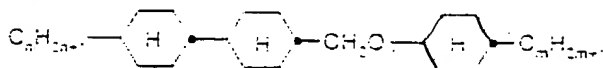


CC-n-OMT

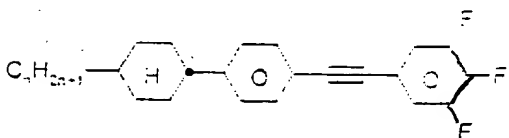
[illegible]



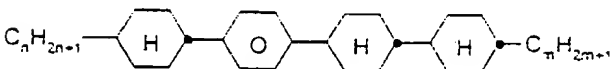
GPTU-n-F



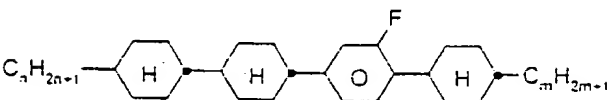
CCOC-n-m



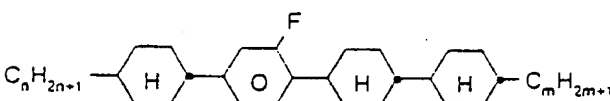
CPTU-n-F



CPCC-n-m



CCGC-n-m



CGCC-n-m

Particularly preferred liquid-crystalline mixtures are those comprising not only one, two or three compounds of the formula I but also one, two, three, four, five, six or more compounds from Table B.

The examples below are intended to illustrate the invention without representing a limitation. Above and below, percentages are percent by weight. All temperatures are given in degrees Celsius. m.p. denotes melting point, cl.p. clearing point. Furthermore, C = crystalline state, N = nematic phase, S = smectic phase and I = isotropic phase. The numbers between these

symbols are the transition temperatures. Δn denotes the optical anisotropy (589 nm, 20°C), and the flow viscosity ν_{20} (mm²/sec) and rotational viscosity γ_1 (mPa·s) were each determined at 20°C.

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V_{10} denotes the voltage for 10% transmission (viewing direction perpendicular to the plate surface). t_{on} denotes the switch-on time and t_{off} the switch-off time at an operating voltage corresponding to twice the value of V_{10} . Δn denotes the optical anisotropy, and n_o the refractive index. $\Delta\epsilon$ denotes the dielectric anisotropy ($\Delta\epsilon = \epsilon_2 - \epsilon_1$, where ϵ_2 denotes the dielectric constant parallel to the longitudinal axis of the molecules, and ϵ_1 denotes the dielectric constant perpendicular thereto). The electro-optical data were measured in a TN cell at the 1st minimum (i.e. at a $d \cdot \Delta n$ value of 0.5) at 20°C, unless expressly stated otherwise. The optical data were measured at 20°C, unless expressly stated otherwise.

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Mixture Examples

Example 1 - Low Δn TFT mixture

| | | | |
|----------------------|-------|--------------------------------------|---------|
| CCH-3CF ₃ | 8.0% | S → N | < -40°C |
| CCH-5CF ₃ | 12.0% | Clearing point: | 72°C |
| CC-5-V | 5.0% | Δn [589 nm, 20°C]: | +0.0578 |
| CCH-3O3 | 5.0% | $\Delta\epsilon$ [1 kHz, 20°C]: | +6.5 |
| CCH-5O1 | 12.0% | γ_1 [mPa·s, 20°C]: | 129 |
| CCP-2F.F.F | 12.0% | $d \cdot \Delta n$ [μ m, 20°C]: | 0.5 |
| CCP-3F.F.F | 6.0% | $V_{10,0,20}$ [V]: | 1.62 |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 19.0% | | |
| CCZU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CCPC-34 | 3.0% | | |

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Example 2 - Low Δn TFT mixture

| | | | |
|-----------------------|-------|---------------------------------------|---------|
| ECCH-5CF ₃ | 20.0% | | |
| CC-5-V | 5.0% | Clearing point: | +74°C |
| CCH-3O3 | 5.0% | Δn [589 nm, 20°C]: | +0.0585 |
| CCH-5O1 | 12.0% | $\Delta \epsilon$ [1 kHz, 20°C]: | +6.5 |
| CCP-2F.F.F | 12.0% | γ_1 [mPa.s, 20°C]: | 141 |
| CCP-3F.F.F | 6.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCZU-2-F | 6.0% | Twist: | 90°C |
| CCZU-3-F | 19.0% | $V_{10,0,20}$ [V]: | 1.69 |
| CCZU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CCPC-34 | 3.0% | | |

5 Example 3 - Low Δn TFT mixture

| | | | |
|--------------------------|-------|---------------------------------------|---------|
| CCH-3CF ₃ | 9.0% | S \rightarrow N | < -30°C |
| CCH-5CF ₃ | 12.0% | Clearing point: | 78.5°C |
| CC-5-V | 5.0% | Δn [589 nm, 20°C]: | +0.0646 |
| CH-33 | 3.0% | $\Delta \epsilon$ [1 kHz, 20°C]: | +8.8 |
| CCP-2F.F.F | 12.0% | γ_1 [mPa.s, 20°C]: | 140 |
| CCP-3F.F.F | 12.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCP-5F.F.F | 5.0% | Twist: | 90°C |
| CCP-2OCF ₃ .F | 6.0% | $V_{10,0,20}$ [V]: | 1.43 |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 20.0% | | |
| CCZU-5-F | 6.0% | | |
| CCPC-34 | 4.0% | | |

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Example 4 - Low Δn TFT mixture

| | | | |
|--------------------------|-------|---------------------------------------|---------|
| ECCH-5CF ₃ | 21.0% | | |
| CC-5-V | 5.0% | Clearing point: | +82.0°C |
| CH-33 | 3.0% | Δn [589 nm, 20°C]: | +0.0654 |
| CCP-2F.F.F | 12.0% | $\Delta \epsilon$ [1 kHz, 20°C]: | +8.5 |
| CCP-3F.F.F | 12.0% | γ_1 [mPa.s, 20°C]: | 165 |
| CCP-5F.F.F | 5.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCP-2OCF ₃ .F | 6.0% | $V_{10,0,20}$ [V]: | 1.49 |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 20.0% | | |
| CCZU-5-F | 6.0% | | |
| CCPC-34 | 4.0% | | |

5 Example 5 - Low Δn TFT mixture

| | | | |
|----------------------|-------|----------------------------|---------|
| CCH-3CF ₃ | 10.0% | S \rightarrow N | < -30°C |
| CCH-5CF ₃ | 14.0% | Clearing point: | +72.0°C |
| CCH-3O2 | 7.0% | Δn [589 nm, 20°C]: | +0.0560 |
| CCH-3O3 | 5.0% | $V_{10,0,20}$ [V]: | 1.87 |
| CCH-5O1 | 12.0% | | |
| CCP-2F.F.F | 9.0% | | |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 19.0% | | |
| CCZU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CH-43 | 2.0% | | |
| CCPC-33 | 2.0% | | |
| CCPC-34 | 2.0% | | |

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Example 6 - Low Δn TFT mixture

| | | | |
|----------------------|-------|----------------------------|---------|
| CCH-3CF ₃ | 8.0% | S → N | < -30°C |
| CCH-5CF ₃ | 12.0% | Clearing point: | +70.5°C |
| OS-33 | 6.0% | Δn [589 nm, 20°C]: | +0.0562 |
| CCH-3O2 | 4.0% | V _{10,020} [V]: | 1.80 |
| CCH-3O3 | 5.0% | | |
| CCH-5O1 | 12.0% | | |
| CCP-2F.F.F | 12.0% | | |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 19.0% | | |
| CCzU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CCPC-33 | 2.0% | | |
| CCPC-34 | 2.0% | | |

5 Example 7 - Low Δn TFT mixture

| | | | |
|-----------------------|-------|----------------------------|---------|
| CCH-3OCF ₃ | 10.0% | | |
| CCH-5OCF ₃ | 14.0% | Clearing point: | +75.5°C |
| CCH-3O2 | 7.0% | Δn [589 nm, 20°C]: | +0.0572 |
| CCH-3O3 | 7.0% | d· Δn [μm, 20°C]: | 0.5 |
| CCH-5O1 | 10.0% | V _{10,0,20} [V]: | 1.74 |
| CCP-2F.F.F | 9.0% | Twist: | 90° |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 19.0% | | |
| CCZU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CH-43 | 3.0% | | |
| CCPC-33 | 3.0% | | |

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Example 8 - Low Δn TFT mixture

| | | | |
|------------|-------|----------------------------------|---------|
| DC-V2-T | 15.0% | S \rightarrow N | < -30°C |
| CCH-302 | 15.0% | Clearing point: | +69.0°C |
| CH-34 | 4.0% | Δn [589 nm, 20°C]: | +0.0568 |
| CCH-501 | 10.0% | d· Δn [μm , 20°C]: | 0.49 |
| CCP-2F.F.F | 12.0% | V _{10,0,20} [V]: | 1.53 |
| CCZU-2-F | 6.0% | Twist: | 90° |
| CCZU-3-F | 20.0% | | |
| CCZU-5-F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CH-43 | 3.0% | | |
| CCPC-33 | 3.0% | | |

5 Example 9 - Low Δn TFT mixture

| | | | |
|----------------------|-------|----------------------------------|---------|
| CCH-301 | 14.0% | S \rightarrow N | < -30°C |
| CCH-501 | 11.0% | Clearing point: | +80.0°C |
| CCP-2F.F.F | 10.0% | Δn [589 nm, 20°C]: | +0.0607 |
| CCP-3F.F.F | 13.0% | d· Δn [μm , 20°C]: | 0.55 |
| CCP-5F.F.F | 5.0% | V _{10,0,20} [V]: | 1.53 |
| CCZU-2-F | 5.0% | Twist: | 90° |
| CCZU-3-F | 17.0% | | |
| CCZU-5-F | 5.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 3.0% | | |
| CH-43 | 3.0% | | |
| CCPC-33 | 3.0% | | |
| CCH-3CF ₃ | 8.0% | | |

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Example 10 - Reflective TN mixture

| | | | |
|----------------------------|-------|---------------------------------------|---------|
| CCH-3O1 | 11.5% | S → N | < -30°C |
| CCP-2F.F.F | 10.0% | Clearing point: | +80.0°C |
| CCP-3F.F.F | 13.0% | Δn [589 nm, 20°C]: | +0.0654 |
| CCP-5F.F.F | 5.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.55 |
| CCZU-2-F | 5.0% | $V_{10,0,20}$ [V]: | 1.38 |
| CCZU-3-F | 16.0% | Twist: | 90° |
| CCZU-5-F | 4.0% | | |
| CCP-2OCF ₂ .F.F | 5.0% | | |
| CCP-3OCF ₂ .F.F | 6.0% | | |
| CCP-5OCF ₂ .F.F | 6.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 2.0% | | |
| CH-43 | 2.5% | | |
| CCH-3CF ₃ | 7.0% | | |
| CCH-5CF ₃ | 4.0% | | |

5 Example 11 - Reflective TN mixture

| | | | |
|----------------------------|-------|---------------------------------------|---------|
| CCH-3O1 | 11.0% | S → N | < -30°C |
| CCP-2F.F.F | 10.0% | Clearing point: | +76.0°C |
| CCP-3F.F.F | 13.0% | Δn [589 nm, 20°C]: | +0.0649 |
| CCP-5F.F.F | 5.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.55 |
| CCZU-2-F | 4.0% | $V_{10,0,20}$ [V]: | 1.39 |
| CCZU-3-F | 15.0% | Twist: | 90° |
| CCZU-5-F | 4.0% | | |
| CCP-2OCF ₂ .F.F | 6.0% | | |
| CCP-3OCF ₂ .F.F | 6.0% | | |
| CCP-5OCF ₂ .F.F | 7.0% | | |
| CH-33 | 3.0% | | |
| CH-43 | 3.0% | | |
| CCH-3CF ₃ | 8.0% | | |
| CCH-5CF ₃ | 5.0% | | |

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| | | | |
|----------------------------|-------|---|---------|
| CCH-3O1 | 6.0% | S → N | < -30°C |
| CCP-2F.F.F | 10.0% | Clearing point: | +80.0°C |
| CCP-3F.F.F | 13.0% | Δn [589 nm, 20°C]: | +0.0652 |
| CCP-5F.F.F | 5.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.55 |
| CCZU-2-F | 5.0% | $V_{10,0,20}$ [V]: | 1.43 |
| CCZU-3-F | 16.0% | Twist: | 90° |
| CCZU-5-F | 4.0% | | |
| CCP-3OCF ₃ .F.F | 6.0% | | |
| CCP-5OCF ₃ .F.F | 6.0% | | |
| CCP-5OCF ₂ .F.F | 5.0% | | |
| CH-33 | 3.0% | | |
| CH-35 | 2.0% | | |
| CH-43 | 2.0% | | |
| CCH-3CF ₃ | 10.0% | | |
| CCH-5CF ₃ | 7.0% | | |

| | | | |
|----------------------|-------|---------------------------------------|---------|
| CCH-501 | 12.0% | S → N | < -40°C |
| CH-33 | 3.0% | Clearing point: | +81.5°C |
| CH-35 | 3.0% | Δn [589 nm, 20°C]: | +0.0604 |
| CH-43 | 3.0% | $\Delta \epsilon$ [1 kHz, 20°C]: | +8.4 |
| CH-45 | 3.0% | γ_1 [mPa.s, 20°C]: | 160 |
| CCP-2F.F.F | 9.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCZU-2-F | 6.0% | $V_{10,0,20}$ [V]: | 1.42 |
| CCZU-3-F | 15.0% | Twist: | 90° |
| CCZU-5-F | 6.0% | | |
| CDU-2-F | 9.0% | | |
| CDU-3-F | 9.0% | | |
| CDU-5-F | 3.0% | | |
| CCH-3CF ₃ | 7.0% | | |
| CCH-5CF ₃ | 8.0% | | |
| CCPC-34 | 4.0% | | |

Example 14 - Low Δn TFT mixture

| | | | |
|----------------------|-------|---------------------------------------|---------|
| CCH-301 | 4.0% | S \rightarrow N | < -40°C |
| CCH-501 | 9.0% | Clearing point: | +80.5°C |
| CH-33 | 3.0% | Δn [589 nm, 20°C]: | +0.0640 |
| CH-35 | 3.0% | $\Delta \epsilon$ [1 kHz, 20°C]: | +7.6 |
| CH-43 | 2.0% | γ_1 [mPa.s, 20°C]: | 161 |
| CCP-2F.F.F | 9.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCP-3F.F.F | 6.0% | $V_{10,0,20}$ [V]: | 1.28 |
| CCZU-2-F | 6.0% | Twist: | 90° |
| CCZU-3-F | 15.0% | | |
| CCZU-5-F | 6.0% | | |
| CDU-2-F | 10.0% | | |
| CDU-3-F | 9.0% | | |
| CDU-5-F | 7.0% | | |
| CCH-3CF ₃ | 7.0% | | |
| CCPC-34 | 4.0% | | |

5 Example 15 - Reflective TN mixture

| | | | |
|-----------------------|-------|---------------------------------------|---------|
| CCH-301 | 12.0% | S \rightarrow N | < -20°C |
| CH-33 | 3.0% | Clearing point: | +93.0°C |
| CH-35 | 3.0% | Δn [589 nm, 20°C]: | +0.0653 |
| CCP-4OCF ₃ | 8.0% | $d \cdot \Delta n$ [μm , 20°C]: | 0.5 |
| CCP-2F.F.F | 12.0% | $V_{10,0,20}$ [V]: | 1.55 |
| CCP-3F.F.F | 12.0% | Twist: | 90° |
| CCP-5F.F.F | 6.0% | | |
| CCZU-2-F | 6.0% | | |
| CCZU-3-F | 13.0% | | |
| CCZU-5-F | 6.0% | | |
| CZC-3-T | 6.0% | | |
| CCZC-3-T | 10.0% | | |
| CCPC-34 | 3.0% | | |

Example 16

| | | | |
|--------------------------|---------|----------------------------------|----------|
| CCH-3CF ₃ | 9.00 % | S → N | < -30 °C |
| CCH-5CF ₃ | 12.00 % | Clearing point: | +80.0 °C |
| CC-5-V | 7.00 % | Δn [589 nm, 20 °C]: | +0.0648 |
| CH-33 | 3.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 12.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 11.00 % | V _{10,0,20} [V]: | 1.49 |
| CCP-5F.F.F | 6.00 % | | |
| CCP-20CF ₃ .F | 7.00 % | | |
| CCZU-2-F | 6.00 % | | |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CCPC-34 | 5.00 % | | |

Example 17

| | | | |
|----------------------|---------|-------------------------------------|----------|
| CCH-501 | 7.00 % | S → N | < -40 °C |
| CH-33 | 3.00 % | Clearing point: | +86.0 °C |
| CH-35 | 3.00 % | Δn [589 nm, 20 °C]: | +0.0645 |
| CH-43 | 3.00 % | $\Delta \varepsilon$ [1kHz, 20 °C]: | +10.2 |
| CCP-2F.F.F | 7.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 5.00 % | Twist [°]: | 90 |
| CCZU-2-F | 6.00 % | V _{10,0,20} [V]: | 1.36 |
| CCZU-3-F | 15.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 9.00 % | | |
| CDU-5-F | 6.00 % | | |
| CCH-3CF ₃ | 7.00 % | | |
| CCH-5CF ₃ | 8.00 % | | |
| CCPC-34 | 3.00 % | | |
| CCPC-33 | 3.00 % | | |

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Example 18

| | | | |
|----------------------|---------|--|----------|
| CCH-501 | 12.00 % | S → N | < -40 °C |
| CH-33 | 3.00 % | Clearing point: | +82.5 °C |
| CH-35 | 3.00 % | Δn [589 nm, 20 °C]: | +0.0608 |
| CH-43 | 3.00 % | d- Δn [20 °C, μm]: | 0.50 |
| CH-45 | 3.00 % | twist [°]: | 90 |
| CCP-2F.F.F | 6.00 % | $V_{10,0,20}$ [V]: | 1.42 |
| CCP-3F.F.F | 4.00 % | | |
| CCZU-2-F | 6.00 % | | |
| CCZU-3-F | 14.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 8.00 % | | |
| CDU-3-F | 8.00 % | | |
| CDU-5-F | 5.00 % | | |
| CCH-3CF ₃ | 8.00 % | | |
| CCH-5CF ₃ | 7.00 % | | |
| CCPC-34 | 4.00 % | | |

Example 19

| | | | |
|--------------------------|---------|--|----------|
| CCH-301 | 5.00 % | S → N | < -40 °C |
| CCH-501 | 16.00 % | Clearing point: | +86.0 °C |
| CCP-2F.F.F | 12.00 % | Δn [589 nm, 20 °C]: | +0.0622 |
| CCP-3F.F.F | 12.00 % | $\Delta \varepsilon$ [1kHz, 20 °C]: | +4.8 |
| CCP-5F.F.F | 6.00 % | d- Δn [20 °C, μm]: | 0.50 |
| CCP-20CF ₃ | 5.00 % | twist [°]: | 90 |
| CCP-40CF ₃ | 6.00 % | $V_{10,0,20}$ [V]: | 1.98 |
| CCP-20CF ₃ .F | 9.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |
| CCPC-34 | 4.00 % | | |
| CCH-3CF ₃ | 6.00 % | | |
| CCH-5CF ₃ | 6.00 % | | |

Example 20

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CH-33 | 3.00 % | S → N | < -40 °C |
| CH-35 | 2.00 % | Clearing point: | +76.5 °C |
| CCP-2F.F.F | 10.00 % | Δn [589 nm, 20 °C]: | +0.0642 |
| CCZU-2-F | 6.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCZU-3-F | 16.00 % | Twist [°]: | 90 |
| CCZU-5-F | 6.00 % | V_{10} [V]: | 1.22 |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 11.00 % | | |
| CDU-5-F | 8.00 % | | |
| CCH-3CF ₃ | 11.00 % | | |
| CCH-5CF ₃ | 11.00 % | | |
| CCPC-33 | 4.00 % | | |
| CCPC-34 | 3.00 % | | |

Example 21

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CH-33 | 4.00 % | S → N | < -40 °C |
| CH-35 | 4.00 % | Clearing point: | +77.0 °C |
| CH-43 | 2.00 % | Δn [589 nm, 20 °C]: | +0.0628 |
| CCP-2F.F.F | 9.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCZU-2-F | 6.00 % | Twist [°]: | 90 |
| CCZU-3-F | 16.00 % | V_{10} [V]: | 1.24 |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 11.00 % | | |
| CDU-5-F | 8.00 % | | |
| CCH-3CF ₃ | 11.00 % | | |
| CCH-5CF ₃ | 10.00 % | | |
| CCPC-34 | 4.00 % | | |

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| | |
|----------------------|---------|
| CH-33 | 4.00 % |
| CH-35 | 3.00 % |
| CCP-2F.F.F | 10.00 % |
| CCZU-2-F | 6.00 % |
| CCZU-3-F | 16.00 % |
| CCZU-5-F | 6.00 % |
| CDU-2-F | 9.00 % |
| CDU-3-F | 11.00 % |
| CDU-5-F | 8.00 % |
| CCH-3CF ₃ | 11.00 % |
| CCH-5CF ₃ | 9.00 % |
| CCPC-33 | 4.00 % |
| CCPC-34 | 3.00 % |

| | |
|--|----------|
| S \rightarrow N | < -30 °C |
| Clearing point: | +82.0 °C |
| Δn [589 nm, 20 °C]: | +0.0645 |
| $\Delta \varepsilon$ [kHz, 20 °C]: | +11.2 |
| d $\cdot\Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V ₁₀ [V]: | 1.27 |

| | |
|----------------------|---------|
| CH-33 | 4.00 % |
| CH-35 | 3.00 % |
| CH-43 | 3.00 % |
| CCP-2F.F.F | 9.00 % |
| CCZU-2-F | 6.00 % |
| CCZU-3-F | 16.00 % |
| CCZU-5-F | 6.00 % |
| CDU-2-F | 9.00 % |
| CDU-3-F | 11.00 % |
| CDU-5-F | 8.00 % |
| CCH-3CF ₃ | 11.00 % |
| CCH-5CF ₃ | 9.00 % |
| CCPC-33 | 2.00 % |
| CCPC-34 | 3.00 % |

| | |
|--|----------|
| S → N | < -30 °C |
| Clearing point: | +81.0 °C |
| Δn [589 nm, 20 °C]: | +0.0637 |
| d- Δn [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V ₁₀ [V]: | 1.26 |

Example 24

| | | | |
|----------------------|---------|----------------------------------|----------|
| CCH-501 | 8.00 % | S → N | < -40 °C |
| CH-33 | 4.00 % | Clearing point: | +82.0 °C |
| CH-35 | 4.00 % | Δn [589 nm, 20 °C]: | +0.0620 |
| CH-43 | 4.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 9.00 % | Twist [°]: | 90 |
| CCZU-2-F | 6.00 % | V_{10} [V]: | 1.36 |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 11.00 % | | |
| CDU-5-F | 3.00 % | | |
| CCH-3CF ₃ | 8.00 % | | |
| CCH-5CF ₃ | 8.00 % | | |
| CCPC-34 | 4.00 % | | |

Example 25

| | | | |
|----------------------|---------|------------------------------------|----------|
| CCH-501 | 12.00 % | S → N | < -40 °C |
| CH-33 | 4.00 % | Clearing point: | +81.0 °C |
| CH-35 | 4.00 % | Δn [589 nm, 20 °C]: | +0.0610 |
| CH-43 | 4.00 % | $\Delta \varepsilon$ [kHz, 20 °C]: | +8.9 |
| CCP-2F.F.F | 9.00 % | γ_1 [mPa·s, 20 °C]: | 154 |
| CCZU-2-F | 6.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCZU-3-F | 16.00 % | Twist [°]: | 90 |
| CCZU-5-F | 6.00 % | V_{10} [V]: | 1.41 |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 11.00 % | | |
| CCH-3CF ₃ | 7.00 % | | |
| CCH-5CF ₃ | 8.00 % | | |
| CCPC-34 | 4.00 % | | |

Example 26

| | | | |
|--------------------------|---------|---------------------------------------|----------|
| CCH-303 | 5.00 % | Clearing point: | +90.0 °C |
| CCH-501 | 16.00 % | Δn [589 nm, 20 °C]: | +0.0628 |
| CCP-2F.F.F | 12.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 12.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 6.00 % | V_{10} [V]: | 2.08 |
| CCP-20CF ₃ | 5.00 % | | |
| CCP-40CF ₃ | 7.00 % | | |
| CCP-20CF ₃ .F | 6.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |
| CCPC-33 | 3.00 % | | |
| CCPC-34 | 2.00 % | | |
| CCH-3CF ₃ | 6.00 % | | |
| CCH-5CF ₃ | 7.00 % | | |

Example 27

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-3CF ₃ | 8.00 % | S → N | < -40 °C |
| CCH-5CF ₃ | 8.00 % | Clearing point: | +87.5 °C |
| CCH-303 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0628 |
| CCH-501 | 6.00 % | $\Delta \varepsilon$ [kHz, 20 °C]: | +7.3 |
| CCP-2F.F.F | 11.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 10.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 5.00 % | V_{10} [V]: | 1.69 |
| CCZU-2-F | 6.00 % | | |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CCPC-33 | 3.00 % | | |
| CCPC-34 | 2.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |

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Example 28

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-3CF ₃ | 6.00 % | S → N | < -40 °C |
| CCH-5CF ₃ | 8.00 % | Clearing point: | +83.5 °C |
| CCH-303 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0620 |
| CCH-501 | 6.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 10.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 7.00 % | V_{10} [V]: | 1.58 |
| CCP-5F.F.F | 5.00 % | | |
| CDU-2-F | 10.00 % | | |
| CDU-3-F | 10.00 % | | |
| CDU-5-F | 8.00 % | | |
| CCPC-33 | 3.00 % | | |
| CCPC-34 | 3.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 4.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

Example 29

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-303 | 15.00 % | S → N | < -30 °C |
| CH-33 | 3.00 % | Clearing point: | +85.0 °C |
| CH-35 | 3.00 % | Δn [589 nm, 20 °C]: | +0.0615 |
| CH-43 | 3.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CH-45 | 3.00 % | Twist [°]: | 90 |
| CCP-2F.F.F | 7.00 % | V_{10} [V]: | 1.53 |
| CCZU-2-F | 6.00 % | | |
| CCZU-3-F | 17.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 10.00 % | | |
| CDU-3-F | 9.00 % | | |
| CCH-3CF ₃ | 7.00 % | | |
| CCH-5CF ₃ | 7.00 % | | |
| CCPC-34 | 4.00 % | | |

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Example 30

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-303 | 11.00 % | | |
| CCH-34 | 5.00 % | Clearing point: | +85.0 °C |
| CH-33 | 4.00 % | Δn [589 nm, 20 °C]: | +0.0607 |
| CH-35 | 4.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CH-43 | 3.00 % | Twist [°]: | 90 |
| CH-45 | 3.00 % | V_{10} [V]: | 1.55 |
| CCP-2F.F.F | 4.00 % | | |
| CCZU-2-F | 6.00 % | | |
| CCZU-3-F | 17.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 10.00 % | | |
| CDU-3-F | 11.00 % | | |
| CCH-3CF ₃ | 7.00 % | | |
| CCH-5CF ₃ | 7.00 % | | |
| CCPC-34 | 2.00 % | | |

Example 31

| | | | |
|----------------------|---------|-----------------------------|----------|
| CCH-3CF ₃ | 6.00 % | S → N | < -20 °C |
| CCH-5CF ₃ | 7.00 % | Clearing point: | +84.0 °C |
| CCH-34 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0617 |
| CC-5-V | 2.00 % | | |
| CCH-303 | 11.50 % | | |
| CCP-2F.F.F | 9.00 % | | |
| CCP-3F.F.F | 5.00 % | | |
| CCP-5F.F.F | 3.00 % | | |
| CDU-2-F | 11.00 % | | |
| CDU-3-F | 11.00 % | | |
| CDU-5-F | 10.00 % | | |
| CCPC-33 | 2.00 % | | |
| CCPC-34 | 3.00 % | | |
| CH-33 | 4.00 % | | |

| | |
|-------|--------|
| CH-35 | 3.50 % |
| CH-43 | 3.50 % |
| CH-45 | 3.50 % |

Example 32

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-303 | 12.00 % | Clearing point: | +86.0 °C |
| CCH-501 | 11.00 % | Δn [589 nm, 20 °C]: | +0.0610 |
| CH-33 | 3.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CH-35 | 3.00 % | Twist [°]: | 90 |
| CH-43 | 3.00 % | V_{10} [V]: | 1.61 |
| CH-45 | 3.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CDU-2-F | 9.00 % | | |
| CDU-3-F | 9.00 % | | |
| CDU-5-F | 7.00 % | | |
| CCH-3CF ₃ | 5.00 % | | |
| CCH-5CF ₃ | 5.00 % | | |
| CCPC-34 | 4.00 % | | |

Example 33

| | | | |
|----------|---------|---------------------------------------|----------|
| CCH-303 | 14.00 % | Clearing point: | +86.0 °C |
| CCH-501 | 11.00 % | Δn [589 nm, 20 °C]: | +0.0612 |
| CH-33 | 2.50 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CH-35 | 2.50 % | Twist [°]: | 90 |
| CH-43 | 3.00 % | V_{10} [V]: | 1.61 |
| CH-45 | 3.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 5.00 % | | |

| | |
|----------------------|--------|
| CDU-2-F | 9.00 % |
| CDU-3-F | 9.00 % |
| CDU-5-F | 8.00 % |
| CCH-3CF ₃ | 4.00 % |
| CCH-5CF ₃ | 4.00 % |
| CCPC-34 | 4.00 % |

Example 34

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 8.00 % | Clearing point: | +84.0 °C |
| CCH-501 | 12.00 % | Δn [589 nm, 20 °C]: | +0.0614 |
| CH-33 | 3.00 % | $\Delta \varepsilon$ [kHz, 20 °C]: | +8.3 |
| CH-35 | 3.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CH-43 | 3.00 % | Twist [°]: | 90 |
| CH-45 | 3.00 % | V_{10} [V]: | 1.48 |
| CCP-2F.F.F | 9.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 8.00 % | | |
| CDU-3-F | 9.00 % | | |
| CDU-5-F | 4.00 % | | |
| CCH-3CF ₃ | 3.00 % | | |
| CCH-5CF ₃ | 4.00 % | | |
| CCPC-34 | 4.00 % | | |

Example 35

| | | | |
|----------------------|---------|---------------------------------------|------------|
| CCH-301 | 13.00 % | S → N | < -30.0 °C |
| CCH-35 | 6.00 % | Clearing point: | +88.5 °C |
| CCH-3CF ₃ | 8.00 % | Δn [589 nm, 20 °C]: | +0.0616 |
| CCP-2F.F.F | 10.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 14.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 6.00 % | V_{10} [V]: | 1.63 |

| | |
|----------|---------|
| CCZU-2-F | 5.00 % |
| CCZU-3-F | 13.00 % |
| CCZU-4-F | 5.00 % |
| CCZU-5-F | 5.00 % |
| CH-33 | 4.00 % |
| CH-35 | 4.00 % |
| CH-43 | 3.00 % |
| CH-45 | 4.00 % |

Example 36

| | |
|----------------------|---------|
| CCH-301 | 13.00 % |
| CCH-35 | 6.00 % |
| PCH-7F | 2.00 % |
| CCH-3CF ₃ | 8.00 % |
| CCP-2F.F.F | 10.00 % |
| CCP-3F.F.F | 14.00 % |
| CCP-5F.F.F | 6.00 % |
| CCZU-2-F | 5.00 % |
| CCZU-3-F | 13.00 % |
| CCZU-4-F | 5.00 % |
| CCZU-5-F | 5.00 % |
| CH-33 | 4.00 % |
| CH-35 | 3.00 % |
| CH-43 | 3.00 % |
| CH-45 | 3.00 % |

| | |
|---------------------------------------|----------|
| Clearing point: | +83.0 °C |
| Δn [589 nm, 20 °C]: | +0.0617 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V_{10} [V]: | 1.51 |

Example 37

| | |
|----------------------|---------|
| CCH-301 | 13.00 % |
| CCH-35 | 6.00 % |
| PCH-7F | 2.00 % |
| CCH-3CF ₃ | 8.00 % |
| CCZU-2-F | 5.00 % |

| | |
|-----------------------------|-----------|
| Clearing point: | +102.0 °C |
| Δn [589 nm, 20 °C]: | +0.0644 |

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| | |
|-----------|---------|
| CCZU-3-F | 13.00 % |
| CCZU-4-F | 5.00 % |
| CCZU-5-F | 5.00 % |
| CCZG-2-OT | 10.00 % |
| CCZG-3-OT | 14.00 % |
| CCZG-5-OT | 6.00 % |
| CH-33 | 4.00 % |
| CH-35 | 3.00 % |
| CH-43 | 3.00 % |
| CH-45 | 3.00 % |

Example 38

| | | | |
|----------------------|---------|----------------------------------|----------|
| CCH-301 | 15.00 % | S → N | < -20 °C |
| CCH-35 | 6.00 % | Clearing point: | +84.5 °C |
| CCH-3CF ₃ | 8.00 % | Δn [589 nm, 20 °C]: | +0.0613 |
| CCP-2F.F.F | 10.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 14.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 6.00 % | V ₁₀ [V]: | 1.58 |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

Example 39

| | | | |
|----------------------|---------|----------------------------------|----------|
| CCH-301 | 13.00 % | S → N | < -20 °C |
| CCH-35 | 6.00 % | Clearing point: | +87.0 °C |
| CCH-3CF ₃ | 8.00 % | Δn [589 nm, 20 °C]: | +0.0623 |
| CCP-2F.F.F | 10.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 14.00 % | Twist [°]: | 90 |

| | | | |
|---------------------------|--------|---------------|------|
| CCP-5F.F.F | 6.00 % | V_{10} [V]: | 1.62 |
| CCP-4CF ₃ .F.F | 6.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 7.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 4.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 4.00 % | | |

Example 40

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 15.00 % | Clearing point: | +85.5 °C |
| CCH-3CF ₃ | 8.00 % | Δn [589 nm, 20 °C]: | +0.0612 |
| CC-5-OMT | 6.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 10.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 14.00 % | V_{10} [V]: | 1.59 |
| CCP-5F.F.F | 6.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CH-33 | 5.00 % | | |
| CH-35 | 4.00 % | | |
| CH-43 | 4.00 % | | |
| CH-45 | 4.00 % | | |

Example 41

| | | | |
|----------------------|---------|-----------------------------|----------|
| CCH-301 | 17.00 % | Clearing point: | +89.5 °C |
| CCH-35 | 6.00 % | Δn [589 nm, 20 °C]: | +0.0617 |
| CCH-3CF ₃ | 8.00 % | | |
| CCP-2F.F.F | 5.00 % | | |
| CCP-3F.F.F | 5.00 % | | |

| | |
|------------|---------|
| CCP-5F.F.F | 5.00 % |
| CCZU-2-F | 5.00 % |
| CCZU-3-F | 13.00 % |
| CCZU-4-F | 5.00 % |
| CCZU-5-F | 5.00 % |
| CCZG-2-OT | 5.00 % |
| CCZG-3-OT | 5.00 % |
| CCZG-5-OT | 5.00 % |
| CH-33 | 3.00 % |
| CH-35 | 3.00 % |
| CH-43 | 3.00 % |
| CH-45 | 2.00 % |

Example 42

| | | | |
|----------------------|---------|-----------------------------|----------|
| CCH-301 | 14.00 % | Clearing point: | +85.5 °C |
| CCH-35 | 11.00 % | Δn [589 nm, 20 °C]: | +0.0601 |
| CCH-3CF ₃ | 8.00 % | | |
| CCP-2F.F.F | 5.00 % | | |
| CCP-3F.F.F | 10.00 % | | |
| CCP-5F.F.F | 6.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 18.00 % | | |
| CCZU-4-F | 8.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 2.00 % | | |
| CH-45 | 2.00 % | | |

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Example 43

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 15.00 % | Clearing point: | +86.0 °C |
| CCH-35 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0605 |
| CCH-3CF ₃ | 8.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 7.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 13.00 % | V_{10} [V]: | 1.70 |
| CCP-5F.F.F | 6.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

Example 44

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 13.00 % | Clearing point: | +86.0 °C |
| CCH-35 | 6.00 % | Δn [589 nm, 20 °C]: | +0.0615 |
| CCH-3CF ₃ | 8.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 13.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 17.00 % | V_{10} [V]: | 1.67 |
| CCP-5F.F.F | 8.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 10.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 4.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 4.00 % | | |

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Example 45

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 12.00 % | Clearing point: | +84.0 °C |
| CCH-35 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0602 |
| CCH-3CF ₃ | 11.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 9.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 12.00 % | V_{10} [V]: | 1.66 |
| CCP-5F.F.F | 5.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

Example 46

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 17.00 % | Clearing point: | +73.5 °C |
| CCH-35 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0585 |
| CCH-3CF ₃ | 11.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 9.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 12.00 % | V_{10} [V]: | 1.59 |
| CCP-5F.F.F | 5.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 2.00 % | | |

Example 47

| | | | |
|--------------------------|---------|---------------------------------------|----------|
| CCH-301 | 14.00 % | S → N | < -40 °C |
| CCH-34 | 4.00 % | Clearing point: | +78.0 °C |
| CC-5-V | 5.00 % | Δn [589 nm, 20 °C]: | +0.0601 |
| CCP-2F.F.F | 10.00 % | $\Delta \epsilon$ [kHz, 20 °C]: | 6.6 |
| CCP-3F.F.F | 12.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-5F.F.F | 6.00 % | Twist [°]: | 90 |
| CCZU-2-F | 5.00 % | V_{10} [V]: | 1.62 |
| CCZU-3-F | 16.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CCP-20CF ₃ .F | 2.00 % | | |
| CCH-3CF ₃ | 10.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 2.00 % | | |

Example 48

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-301 | 12.00 % | Clearing point: | +85.0 °C |
| CCH-35 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0602 |
| CCH-3CF ₃ | 6.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCH-5CF ₃ | 5.00 % | Twist [°]: | 90 |
| CCP-2F.F.F | 9.00 % | V_{10} [V]: | 1.72 |
| CCP-3F.F.F | 12.00 % | | |
| CCP-5F.F.F | 5.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 13.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 4.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

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Example 49

| | | | |
|----------------------|--------|---------------------------------------|----------|
| CCH-301 | 8.00 % | Clearing point: | +83.5 °C |
| CCH-501 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0603 |
| CCH-35 | 7.00 % | $\Delta \varepsilon$ [kHz, 20 °C]: | +7.3 |
| CC-5-V | 3.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCH-3CF ₃ | 6.00 % | Twist [°]: | 90 |
| CCH-5CF ₃ | 5.00 % | V_{10} [V]: | 1.72 |
| CCP-2F.F.F | 7.00 % | | |
| CCP-3F.F.F | 8.00 % | | |
| CCP-4F.F.F | 6.00 % | | |
| CCP-5F.F.F | 5.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 8.00 % | | |
| CCZU-4-F | 5.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CCZG-2-OT | 5.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CH-45 | 3.00 % | | |

Example 50

| | | | |
|------------|---------|---------------------------------------|----------|
| CCH-301 | 5.00 % | S → N | < -30 °C |
| CH-33 | 3.00 % | Clearing point: | +68.0 °C |
| CH-35 | 3.00 % | Δn [589 nm, 20 °C]: | +0.0602 |
| CCP-2F.F.F | 6.00 % | $\Delta \varepsilon$ [kHz, 20 °C]: | +10.3 |
| CCZU-2-F | 6.00 % | γ_1 [mPa·s, 20 °C]: | 161 |
| CCZU-3-F | 16.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCZU-5-F | 6.00 % | Twist [°]: | 90 |
| CDU-2-F | 10.00 % | V_{10} [V]: | 1.22 |
| CDU-3-F | 12.00 % | | |
| CDU-5-F | 8.00 % | | |

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| | |
|----------------------|---------|
| CCH-3CF ₃ | 9.00 % |
| CCH-5CF ₃ | 12.00 % |
| CCPC-34 | 4.00 % |

Example 51

| | |
|----------------------|---------|
| CH-33 | 4.00 % |
| CCP-2F.F.F | 10.00 % |
| CCP-3F.F.F | 2.00 % |
| CCZU-2-F | 6.00 % |
| CCZU-3-F | 16.00 % |
| CCZU-5-F | 6.00 % |
| CDU-2-F | 10.00 % |
| CDU-3-F | 12.00 % |
| CDU-5-F | 8.00 % |
| CCH-3CF ₃ | 9.00 % |
| CCH-5CF ₃ | 12.00 % |
| CCPC-33 | 2.00 % |
| CCPC-34 | 3.00 % |

| | |
|---------------------------------------|----------|
| Clearing point: | +74.0 °C |
| Δn [589 nm, 20 °C]: | +0.0631 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V_{10} [V]: | 1.21 |

Example 52

| | |
|----------------------|---------|
| CH-33 | 4.00 % |
| CCP-2F.F.F | 10.00 % |
| CCP-3F.F.F | 4.00 % |
| CCZU-2-F | 6.00 % |
| CCZU-3-F | 16.00 % |
| CCZU-5-F | 6.00 % |
| CDU-2-F | 9.00 % |
| CDU-3-F | 11.00 % |
| CDU-5-F | 7.00 % |
| CCH-3CF ₃ | 10.00 % |
| CCH-5CF ₃ | 12.00 % |
| CCPC-33 | 2.00 % |
| CCPC-34 | 3.00 % |

| | |
|---------------------------------------|----------|
| Clearing point: | +69.0 °C |
| Δn [589 nm, 20 °C]: | +0.0625 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V_{10} [V]: | 1.16 |

| | |
|--------------------------|---------|
| CCH-34 | 6.00 % |
| CCH-3CF ₃ | 3.00 % |
| CCH-5CF ₃ | 8.00 % |
| CCP-2F.F.F | 11.00 % |
| CCP-3F.F.F | 10.00 % |
| CCP-5F.F.F | 6.00 % |
| CCP-2OCF ₃ .F | 4.00 % |
| CCP-4OCF ₃ | 8.00 % |
| CDU-2-F | 10.00 % |
| CDU-3-F | 12.00 % |
| CDU-5-F | 10.00 % |
| CCOC-3-3 | 4.00 % |
| CCOC-4-3 | 8.00 % |

| | |
|---------------------------------------|----------|
| S \rightarrow N | < -40 °C |
| Clearing point: | +75.0 °C |
| Δn [589 nm, 20 °C]: | +0.0644 |
| $\Delta \epsilon$ [kHz, 20 °C]: | +10.1 |
| d Δn [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V ₁₀ [V]: | 1.34 |

| | |
|--------------------------|---------|
| CCH-34 | 5.00 % |
| CC-5-V | 8.00 % |
| CCH-3CF ₃ | 6.00 % |
| CCH-5CF ₃ | 8.00 % |
| CCP-2F.F.F | 11.00 % |
| CCP-3F.F.F | 11.00 % |
| CCP-5F.F.F | 6.00 % |
| CCZU-2-F | 6.00 % |
| CCZU-3-F | 14.00 % |
| CCZU-5-F | 6.00 % |
| CCP-20CF ₃ .F | 8.00 % |
| CCP-40CF ₃ | 4.00 % |
| CCOC-4-3 | 5.00 % |
| CCOC-3-3 | 2.00 % |

| | |
|---|----------|
| Clearing point: | +80.0 °C |
| Δn [589 nm, 20 °C]: | +0.0642 |
| $\Delta \varepsilon$ [kHz, 20 °C]: | +7.8 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| $V_{1/2}$ [V]: | 1.58 |

Example 55

| | | | |
|--------------------------|---------|---------------------------------------|----------|
| CCH-34 | 5.00 % | S → N | < -40 °C |
| CC-5-V | 8.00 % | Clearing point: | +80.5 °C |
| CCH-3CF ₃ | 6.00 % | Δn [589 nm, 20 °C]: | +0.0643 |
| CCH-5CF ₃ | 8.00 % | $\Delta \epsilon$ [kHz, 20 °C]: | +7.8 |
| CCP-2F.F.F | 11.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 11.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 6.00 % | V_{10} [V]: | 1.59 |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 15.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CCP-20CF ₃ .F | 8.00 % | | |
| CCP-40CF ₃ | 5.00 % | | |
| CCOC-4-3 | 5.00 % | | |
| CCOC-3-3 | 2.00 % | | |

Example 56

| | | | |
|--------------------------|---------|---------------------------------------|----------|
| CCH-34 | 5.00 % | S → N | < -40 °C |
| CC-5-V | 6.00 % | Clearing point: | +80.0 °C |
| CCH-3CF ₃ | 6.00 % | Δn [589 nm, 20 °C]: | +0.0648 |
| CCH-5CF ₃ | 6.00% | $\Delta \epsilon$ [kHz, 20 °C]: | +8.0 |
| CCP-2F.F.F | 12.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 11.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 6.00 % | V_{10} [V]: | 1.54 |
| CCP-20CF ₃ .F | 8.00 % | | |
| CCP-50CF ₃ .F | 8.00 % | | |
| CCP-40CF ₃ | 6.00 % | | |
| CDU-2-F | 6.00 % | | |
| CDU-3-F | 8.00 % | | |
| CCOC-3-3 | 4.00 % | | |
| CCOC-4-3 | 8.00 % | | |

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Example 57

| | | | |
|--------------------------|---------|--|----------|
| CCH-34 | 5.00 % | S → N | < -40 °C |
| CC-5-V | 6.00 % | Clearing point: | +80.5 °C |
| CCH-3CF ₃ | 6.00 % | $\Delta\epsilon$ [kHz, 20 °C]: | +7.9 |
| CCH-5CF ₃ | 8.00 % | γ_1 [mPa·s, 20 °C]: | 124 |
| CCP-2F.F.F | 11.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 12.00 % | Twist [°]: | 90 |
| CCP-5F.F.F | 5.00 % | V ₁₀ [V]: | 1.56 |
| CCZU-2-F | 5.00 % | | |
| CCZU-3-F | 15.00 % | | |
| CCZU-5-F | 4.00 % | | |
| CCP-20CF ₃ .F | 10.50 % | | |
| CCP-40CF ₃ | 6.50 % | | |
| CCOC-4-3 | 4.00 % | | |
| CCOC-3-3 | 2.00 % | | |

Example 58

| | | | |
|----------------------|---------|--|----------|
| CCH-301 | 10.00 % | S → N | < -40 °C |
| CCH-501 | 9.00 % | Clearing point: | +95.5 °C |
| CCH-35 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0608 |
| CC-5-V | 12.00 % | V ₁₀ [V]: | 2.32 |
| CC-3-V1 | 5.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCH-3CF ₃ | 4.00 % | Twist [°]: | 90 |
| CCH-5CF ₃ | 5.00 % | | |
| CCP-2F.F.F | 6.00 % | | |
| CDU-2-F | 6.00 % | | |
| CDU-3-F | 8.00 % | | |
| CCZU-3-F | 7.00 % | | |
| CCPC-33 | 4.00 % | | |
| CCPC-34 | 5.00 % | | |
| CCPC-35 | 4.00 % | | |

| | |
|----------|--------|
| CCOC-3-3 | 3.00 % |
| CCOC-4-3 | 5.00 % |
| CCOC-3-5 | 2.00 % |

Example 59

| | | | |
|----------------------|---------|----------------------------------|----------|
| CCH-301 | 10.00 % | S → N | < -40 °C |
| CCH-501 | 8.00 % | Clearing point: | +95.0 °C |
| CCH-35 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0607 |
| CC-5-V | 15.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CC-3-V1 | 4.00 % | Twist [°]: | 90 |
| CCH-3CF ₃ | 4.00 % | V ₁₀ [V]: | 2.32 |
| CCH-5CF ₃ | 4.00 % | | |
| CCP-2F.F.F | 7.00 % | | |
| CDU-2-F | 7.00 % | | |
| CDU-3-F | 7.00 % | | |
| CCZU-3-F | 6.00 % | | |
| CCPC-33 | 4.00 % | | |
| CCPC-34 | 5.00 % | | |
| CCPC-35 | 4.00 % | | |
| CCOC-3-3 | 3.00 % | | |
| CCOC-4-3 | 5.00 % | | |
| CCOC-3-5 | 2.00 % | | |

Example 60

| | | | |
|----------------------|---------|----------------------------------|----------|
| CCH-301 | 10.00 % | S → N | < -40 °C |
| CCH-501 | 11.00 % | Clearing point: | +95.5 °C |
| CCH-35 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0609 |
| CC-5-V | 9.00 % | d· Δn [20 °C, μm]: | 0.50 |
| CCH-3CF ₃ | 4.00 % | Twist [°]: | 90 |
| CCH-5CF ₃ | 6.00 % | V ₁₀ [V]: | 2.27 |
| CCP-2F.F.F | 6.00 % | | |
| CDU-2-F | 6.00 % | | |

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| | |
|----------|--------|
| CDU-3-F | 8.00 % |
| CCZU-3-F | 7.00 % |
| CCOC-3-3 | 3.00 % |
| CCOC-4-3 | 5.00 % |
| CCOC-3-5 | 2.00 % |
| CCGC-3-3 | 2.00 % |
| CCGC-3-5 | 3.00 % |
| CGCC-2-3 | 5.00 % |
| CGCC-2-5 | 5.00 % |
| CH-43 | 3.00 % |

Example 61

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-35 | 5.00 % | Clearing point: | +95.0 °C |
| CC-3-V1 | 10.00 % | Δn [589 nm, 20 °C]: | +0.0641 |
| CC-5-V | 18.00 % | V_{10} [V]: | 2.34 |
| CCH-3CF ₃ | 8.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCH-5CF ₃ | 10.00 % | Twist [°]: | 90 |
| CCP-2F.F.F | 6.00 % | | |
| CDU-2-F | 8.00 % | | |
| CDU-3-F | 10.00 % | | |
| CGCC-2-3 | 5.00 % | | |
| CGCC-2-5 | 4.00 % | | |
| CCGC-3-2 | 5.00 % | | |
| CCGC-3-5 | 3.00 % | | |
| CCOC-3-3 | 3.00 % | | |
| CCOC-4-3 | 5.00 % | | |

Example 62

| | | | |
|---------|---------|-----------------------------|----------|
| CCH-301 | 9.00 % | S → N | < -40 °C |
| CCH-501 | 10.00 % | Clearing point: | +96.0 °C |
| CCH-35 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0615 |
| CC-5-V | 9.00 % | V_{10} [V]: | 2.25 |

| | | | |
|----------------------|---------|-------------------|------|
| CCH-3CF ₃ | 3.00 % | d·Δn [20 °C, μm]: | 0.50 |
| CCH-5CF ₃ | 8.00 % | Twist [°]: | 90 |
| CCP-2F.F.F | 8.00 % | | |
| CDU-2-F | 8.00 % | | |
| CDU-3-F | 10.00 % | | |
| CCOC-3-3 | 3.00 % | | |
| CCOC-4-3 | 5.00 % | | |
| CCOC-3-5 | 2.00 % | | |
| CCGC-3-2 | 4.00 % | | |
| CCGC-3-5 | 3.00 % | | |
| CGCC-2-3 | 5.00 % | | |
| CGCC-2-5 | 5.00 % | | |
| CH-43 | 3.00 % | | |

Example 63

| | | | |
|----------------------|---------|----------------------|----------|
| CCH-301 | 9.00 % | S → N | < -40 °C |
| CCH-501 | 9.00 % | Clearing point: | +95.0 °C |
| CCH-35 | 5.00 % | Δn [589 nm, 20 °C]: | +0.0608 |
| CC-5-V | 14.00 % | V ₁₀ [V]: | 2.26 |
| CC-3-V1 | 3.00 % | d·Δn [20 °C, μm]: | 0.50 |
| CCH-3CF ₃ | 4.00 % | Twist [°]: | 90 |
| CCH-5CF ₃ | 5.00 % | | |
| CCP-2F.F.F | 5.00 % | | |
| CDU-2-F | 6.00 % | | |
| CDU-3-F | 7.00 % | | |
| CCZU-3-F | 8.50 % | | |
| CCZU-5-F | 3.00 % | | |
| CCPC-33 | 4.00 % | | |
| CCPC-34 | 4.00 % | | |
| CCPC-35 | 4.00 % | | |
| CCOC-3-3 | 3.00 % | | |
| CCOC-4-3 | 4.50 % | | |
| CCOC-3-5 | 2.00 % | | |

Example 64

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-3CF ₃ | 7.00 % | Clearing point: | +83.0 °C |
| CCH-5CF ₃ | 7.00 % | Δn [589 nm, 20 °C]: | +0.0639 |
| CCH-301 | 8.00 % | V_{10} [V]: | 1.38 |
| CCP-2F.F.F | 6.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-3F.F.F | 6.00 % | Twist [°]: | 90 |
| CCP-4F.F.F | 5.00 % | | |
| CCP-5F.F.F | 6.00 % | | |
| CCZU-2-F | 8.00 % | | |
| CCZU-3-F | 10.00 % | | |
| CCZU-4-F | 9.00 % | | |
| CCZU-5-F | 8.00 % | | |
| CCZG-3-OT | 5.00 % | | |
| CCZG-5-OT | 5.00 % | | |
| CCZG-2-OT | 5.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 2.00 % | | |

Example 65

| | | | |
|----------------------|---------|---------------------------------------|----------|
| CCH-3CF ₃ | 4.00 % | Clearing point: | +80.5 °C |
| CCH-5CF ₃ | 4.00 % | Δn [589 nm, 20 °C]: | +0.0641 |
| CCH-301 | 10.00 % | V_{10} [V]: | 1.39 |
| CCH-501 | 10.00 % | $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| CCP-2F.F.F | 9.00 % | Twist [°]: | 90 |
| CCP-3F.F.F | 6.00 % | | |
| CCZU-3-F | 15.00 % | | |
| CCZU-5-F | 6.00 % | | |
| CDU-2-F | 10.00 % | | |
| CDU-3-F | 9.00 % | | |
| CDU-5-F | 7.00 % | | |
| CCPC-33 | 5.00 % | | |
| CCPC-35 | 5.00 % | | |

| | |
|----------------------|---------|
| CCH-3CF ₃ | 4.00 % |
| CCH-5CF ₃ | 4.00 % |
| CCH-301 | 10.00 % |
| CCH-501 | 10.00 % |
| CCP-2F.F.F | 9.00 % |
| CCP-3F.F.F | 6.00 % |
| CCZU-3-F | 15.00 % |
| CCZU-5-F | 6.00 % |
| CDU-2-F | 10.00 % |
| CDU-3-F | 9.00 % |
| CDU-5-F | 7.00 % |
| CPCC-2-2 | 5.00 % |
| CPCC-2-3 | 5.00 % |

| | |
|---|----------|
| Clearing point: | +75.0 °C |
| Δn [589 nm, 20 °C]: | +0.0633 |
| V_{10} [V]: | 1.34 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |

| | |
|----------------------------|---------|
| CCH-301 | 4.00 % |
| CCH-501 | 5.50 % |
| CCP-2F.F.F | 10.00 % |
| CCP-3F.F.F | 12.00 % |
| CCP-5F.F.F | 5.00 % |
| CCZU-2-F | 4.00 % |
| CCZU-3-F | 17.00 % |
| CCZU-5-F | 4.00 % |
| CCP-20CF ₂ .F.F | 3.00 % |
| CCP-30CF ₂ .F.F | 7.00 % |
| CCP-50CF ₂ .F.F | 7.00 % |
| CH-33 | 3.50 % |
| CH-35 | 3.00 % |
| CH-43 | 4.00 % |
| CCH-3CF ₃ | 6.00 % |
| CCH-5CF ₃ | 5.00 % |

| | |
|---|----------|
| S \rightarrow N | < -40 °C |
| Clearing point: | +88.0 °C |
| Δn [589 nm, 20 °C]: | +0.0650 |
| $\Delta \varepsilon$ [kHz, 20 °C]: | +8.2 |
| $d \cdot \Delta n$ [20 °C, μm]: | 0.50 |
| Twist [°]: | 90 |
| V_{10} [V]: | 1.52 |

Example 68

| | | | |
|----------------------|---------|---------------------------------|----------|
| CCH-301 | 12.00 % | S → N | < -30 °C |
| CCH-501 | 8.00 % | Clearing point: | +80.0 °C |
| CC-5-V | 8.00 % | Δn [589 nm, 20 °C]: | +0.0606 |
| CCP-2F.F.F | 10.00 % | $\Delta \epsilon$ [kHz, 20 °C]: | +6.3 |
| CCP-3F.F.F | 12.00 % | | |
| CCP-5F.F.F | 5.00 % | | |
| CCZU-2-F | 5.00 % | | |
| CCzU-3-F | 17.00 % | | |
| CCZU-5-F | 5.00 % | | |
| CH-33 | 3.00 % | | |
| CH-35 | 3.00 % | | |
| CH-43 | 3.00 % | | |
| CCH-3CF ₃ | 7.00 % | | |
| CCPC-33 | 2.00 % | | |

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